DS07-12547-4E

8-bit Original Microcontroller cmos

F²MC-8L MB89530A Series

MB89535A/537A/537AC/538A/538AC/F538 MB89P538/PV530

DESCRIPTION

The MB89530A series is a one-chip microcontroller featuring the F²MC-8L core supporting low-voltage and high-speed operation. Built-in peripheral functions include timers, serial interface, A/D converter, and external interrupt. This product is an ideal general-purpose one-chip microcontroller for a wide variety of applications from household to industrial equipment, as well as use in portable devices.

■ FEATURES

- Wide range of package options
 - Two types of QFP packages (1 mm pitch, 0.65 mm pitch)
 - LQFP package (0.5 mm pitch)
 - SH-DIP package
- Low voltage, high-speed operating capability
 - Minimum instruction execution time 0.32 μs (at base oscillator 12.5 MHz)
- F²MC-8L CPU Core
 - Instruction set optimized for controller operation
 - Multiplication/division instructions
 - 16-bit calculation
 - Branching instructions with bit testing
 - Bit operation instructions, etc.
- · Five timer systems
 - 8-bit PWM timer with 2 channels (usable as either interval timer of PWM timer)
 - Pulse width count timer (supports continuous measurement or remote control receiving applications)
 - 16-bit timer counter
 - 21-bit time base timer
 - Watch prescaler (17-bit)
- UART
 - Synchronous or asynchronous operation, switchable
- 2 serial interfaces (Serial I/O)
 - Selection of transfer direction (specify MSB first or LSB first) for communication with a variety of devices

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- 10-bit A/D converter (8 channels)
 - External clock input for startup support
 - Time base timer output for startup support (except MB89F538)
- Pulse generators (PPG) with 2-program capability
 - 6-bit PPG with selection of pulse width and pulse period
 - 12-bit PPG (2 channels) with selection of pulse width and pulse period
- I2C interface circuits
- External interrupt 1 (single-clock system : 4 channels, dual-clock system : 3 channels)
 - 4 or 3 independent inputs, release enabled from standby mode (includes edge detection function)
- External interrupt 2 (8 channels)
 - 8 independent inputs, release enabled form standby mode (includes level edge detection function)
- Standby modes (low power consumption modes)
 - Stop mode (oscillator stops, virtually no power consumed)
 - Sleep mode (CPU stops, power consumption reduced to one-third)
 - Sub clock mode
 - Watch mode
- Watchdog timer reset
- I/O ports
 - Maximum ports

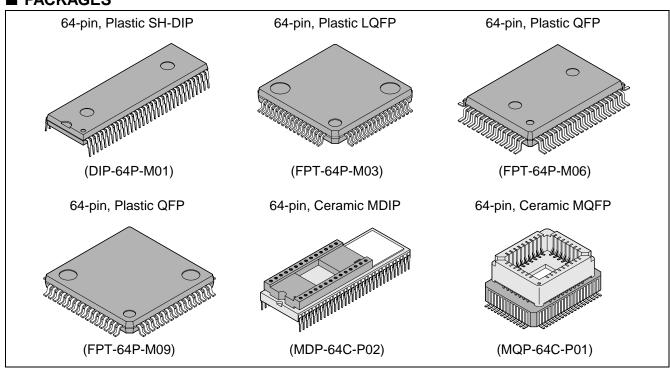
Single-clock system: Except MB89F538 53 ports

: MB89F538 52 ports
Dual-clock system : Except MB89F538 51 ports

: MB89F538 50 ports

- 38 general-purpose I/O ports (CMOS) (MB89F538 : 37 general-purpose I/O ports)
- 2 general-purpose I/O ports (N-ch open drain)
- 8 general-purpose output ports (N-ch open drain)
- General-purpose input ports (CMOS) : single-clock system : 5 ports, dual-clock system : 3 ports

■ PACKAGES



■ PRODUCT LINEUP

Do	Part number	MB89535A	MB89537A/ 537AC	MB89538A/ 538AC	MB89F538	MB89P538	MB89PV530	
Type Mass prod			roduced (Masl	k ROM)	Flash memory	One-time programmable	Evaluation	
ROM capacity		16 K × 8-bit (built-in ROM)	32 K × 8-bit (built-in ROM)	48 K × 8-bit (built-in ROM)	48 K × 8-bit (built-in Flash memory) (write from general purpose EPROM writer)	48 K × 8-bit (built-in ROM) (write from general purpose EPROM writer)	48 K × 8-bit (external ROM) *2	
RA	M capacity	512 byte × 8-bit	1 K × 8-bit		2 K >	< 8-bit		
Ор	erating voltage		2.2 V to 5.5 V * /537A/538A/53		3.5 V to 5.5 V	2.7 V to 5.5 V	2.7 V to 5.5 V	
СР	Basic instructions : 136 Instruction bit length : 8-bits Instruction length : 1 bit to 3 bits Data bit length : 1, 8, 16-bits Minimum instruction execution time : 0.32 µs / 12.5 MHz Minimum interrupt processing time : 2.88 µs / 12.5 MHz							
pheral functions	Ports	Input ports : single-clock system : 5 (4 also usable as external interrupts) dual-clock system : 3 (3 also usable as external interrupts) Output-only ports (N-ch open drain) : 8 (8 also usable as ADC input) I/O ports (N-ch open drain) : 2 (2 also usable as SO2/SDA or SI2/SCL) I/O ports (CMOS) (Except MB89F538) : 38 I/O ports (CMOS) (MB89F538) : 37 (21 have no other function) Total (except MB89F538) : single-clock system : 53 dual-clock system : 51 Total (MB89F538) : single-clock system : 52						
Peri	Time base timer	dual-clock system : 50 21 bits Interrupt periods at main clock oscillation frequency of 12.5 MHz (approx. 0.655 ms, 2.621 ms, 20.97 ms, 335.5 ms)						
	Watchdog timer	Reset period of approx. 167.8 ms to 335.6 ms at main clock frequency of 12.5 MHz Reset period of approx. 500 ms to 1000 ms at sub clock frequency of 32.768 kHz.						
	PWM timer	8-bit interval timer operation (supports square wave output, operating clock period : 1, 8, 16, 64 t _{inst} *3) Pulse width measurement with 8-bit resolution (conversion period : 2 ⁸ t _{inst} *3 to 2 ⁸ × 64 t _{inst} *3 2 channels (can also be used as interval timer, can also be used as ch1 output and ch2 couclock)						
Wa	atch prescaler				uency of 32.768 k 2.00 s, 4.00 s)	Hz		

(Continued)

(Continued) Part number										
i di tiidii.	MB89535A	MB89537A/ 537AC	MB89538A/ 538AC	MB89F538	MB89P538	MB89PV530				
Parameter										
Pulse width count timer	(supports undo 8-bit reload tim (supports squa 8-bit pulse widt (continuous m	8-bit one-shot timer operation (supports underflow output, operating clock period : 1, 4, 32 t _{inst} *3, external) 8-bit reload timer operation (supports square wave output, operating clock period : 1, 4, 32 t _{inst} *3, external) 8-bit pulse width measurement operation (continuous measurement, H width measurement, L width measurement, ↑ to ↑, ↓ to ↓, H width measurement and ↑ to↑)								
16-bit timer/ counter			ng clock period : (select rising, fa							
Serial I/O		BB first or MSB f (2, 8, 32 t _{inst} *3, e								
su UART/SIO	without parity b	CLK synchronous/CLK asynchronous data transfer capability (8, 9 bit with parity bit, or 7,8 bit without parity bit). Built-in baud rate generator provides selection of 14 baud rate settings.								
TRANUT TR	7, 8, 9 bit without Built-in baud ra	CLK synchronous/CLK asynchronous data transfer capability (4, 6, 7, 8 bit with parity bit, or 5, 7, 8, 9 bit without parity bit). Built-in baud rate generator provides selection of 14 baud rate settings. External clock output, 2-channel 8-bit PWM timer output also available for baud rate settings.								
External interrupt 1	Selection of ris	ing, falling, or bo	els independent, oth edge detecti standby mode	on.		·				
External interrupt 2		538 : 8 ch, MB8 or recovery from								
6-bit PPG, 12-bit PPG		el or 12-bit × 2 d		·						
I ² C bus interface	_	1-channel , compatible with Intel System Administrator bus version 1.0 and Philips I ² C specifications. 2-line communications (on MB89PV530/P538/F538/537AC/538AC)								
A/D converte	A/D conversion Supports repea	10-bit resolution × 8 channels. A/D conversion functions (conversion time : 60 t _{inst} *3) Supports repeated calls from external clock (except MB89F538) . Supports repeated calls from internal clock. Standard voltage input provided (AVR)								
Standby modes (power saving modes)	Sleep mode, st	Sleep mode, stop mode, sub clock mode, watch mode.								
Process	CMOS	CMOS								

^{*1 :} Depends on operating frequency.

Note: MB89535A/537A/538A have no built-in I²C functions.

To use I²C functions, choose the MB89PV530/MB89P538/F538/537AC/538AC.

^{*2 :} Using external ROM and MBM27C512.

^{*3 :} t_{inst} represents instruction execution time. This can be selected as 1/4, 1/8, 1/16, 1/64 of the main clock cycle or 1/2 of the sub clock cycle.

■ MODEL DIFFERENCES AND SELECTION CONSIDERATIONS

Part number Package	MB89535A	MB89537A/ 537AC	MB89538A/ 538AC	MB89F538	MB89P538	MB89PV530
DIP-64P-M01	0	0	0	0	0	Х
FPT-64P-M03	0	0	0	Х	Х	Х
FPT-64P-M06	0	0	0	0	0	Х
FPT-64P-M09	0	0	0	0	0	Х
MDP-64C-P02	Х	Х	Х	Х	Х	0
MQP-64C-P01	Х	Х	Х	Х	Х	0

O: Model-package combination available

X : Model-package combination not available

Conversion sockets for pin pitch conversion (manufactured by Sunhayato Corp.) can be used.

Contact : Sunhayato Corp. : TEL : +81-3-3984-7791 FAX : +81-3-3971-0535

E-mail: adapter@sunhayato.co.jp

■ DIFFERENCES AMONG PRODUCTS

1. Memory Capacity

When this product is used in a piggy-back or other evaluation configuration, it is necessary to carefully confirm the differences between the model being used and the product it is evaluating. Particular attention should be given to the following (see "**ECPU CORE 1.Memory Space**").

- The program ROM area starts from address 4000_H on the MB89F538, MB89P538 and MB89PV530 models.
- Note upper limits on RAM, such as stack areas, etc.

2. Current Consumption

- On the MB89PV530, the additional current consumed by the EPROM is added at the connecting socket on the back side.
- When operating at low speed, the current consumption in the one-time PROM or EPROM models is greater than on the mask ROM models. However, current consumption in sleep or stop modes is identical.

For details, refer to "**ELECTRICAL CHARACTERISTICS**".

3. Mask Options

The options available for use, and the method of specifying options, differ according to the model. Before use, check the "MASK OPTIONS" specification section.

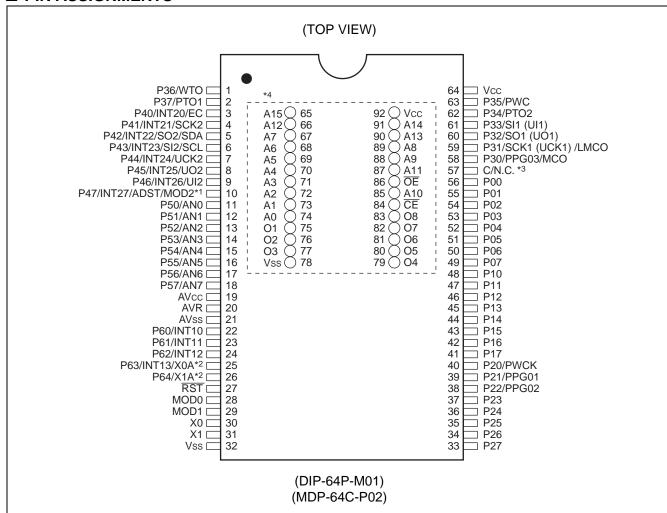
4. Wild Register Functions

The following table shows areas in which wild register functions can be used.

Wild Register Usage Areas

Part number	Address space
MB89PV530	4000н to FFFFн
MB89P538	4000н to FFFFн
MB89F538	4000н to FFFFн
MB89537A/537AC	8000н to FFFFн
MB89538A/538AC	4000н to FFFFн
MB89535A	C000н to FFFFн

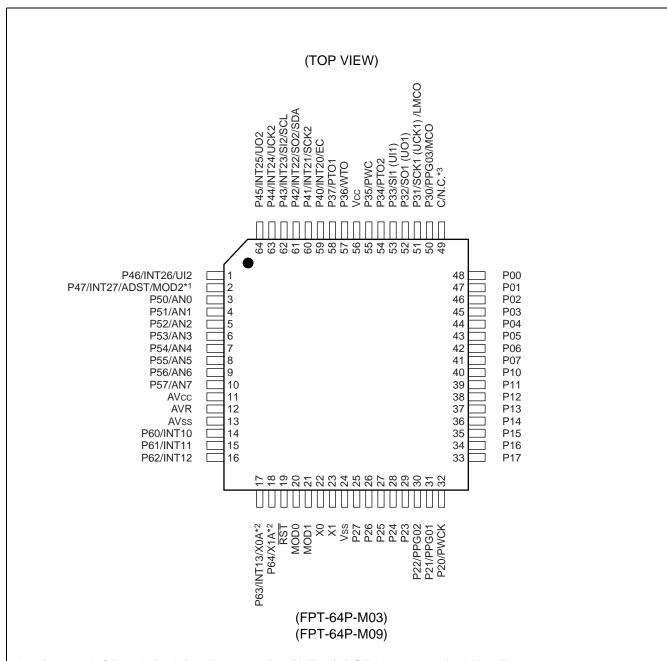
■ PIN ASSIGNMENTS



- *1 : Pin 10 is MOD2 pin for MB89F538 and P47/INT27/ADST pins except for MB89F538.
- *2 : Pin 25 and pin 26 are P63/INT13, P64 pins for single-clock system and X0A, X1A pins for dual-clock system.
- *3 : The function of pin 57 depends on the model. For details, see "■PIN DESCRIPTIONS" and "■HANDLING DEVICES".
- *4 : Package top pin assignments (MB89PV530 only)

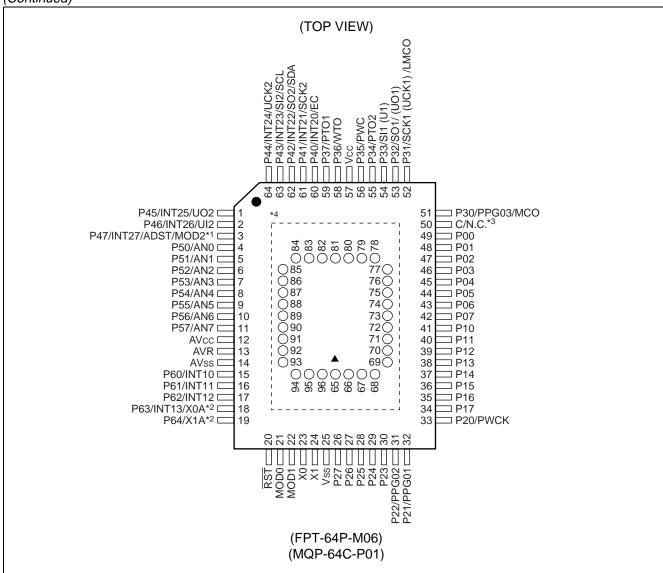
Pin no.	Pin name						
65	A15	73	A1	81	O6	89	A8
66	A12	74	A0	82	07	90	A13
67	A7	75	01	83	O8	91	A14
68	A6	76	02	84	CE	92	Vcc
69	A5	77	O3	85	A10		
70	A4	78	Vss	86	ŌĒ		
71	A3	79	04	87	A11		
72	A2	80	O5	88	A9		

N.C.: Internal connection only. Not for use.



- *1 : Pin 2 is MOD2 pin for MB89F538 and P47/INT27/ADST pins except for MB89F538.
- *2 : Pin 17 and pin 18 are P63/INT13, P64 pins for single-clock system and X0A, X1A pins for dual-clock system.
- *3 : The function of pin 49 depends on the model. For details, see "■PIN DESCRIPTIONS" and "■HANDLING DEVICES".





- *1 : Pin 3 is MOD2 pin for MB89F538 and P47/INT27/ADST pins except for MB89F538.
- *2 : Pin 18 and pin 19 are P63/INT13, P64 pins for single-clock system and X0A, X1A pins for dual-clock system.
- *3 : The function of pin 50 depends on the model. For details, see "■PIN DESCRIPTIONS" and "■HANDLING DEVICES".
- *4 : Package top pin assignments (MB89PV530 only)

Pin no.	Pin name						
65	N.C.	73	A2	81	N.C.	89	ŌĒ
66	A15	74	A1	82	O4	90	N.C.
67	A12	75	A0	83	O5	91	A11
68	A7	76	N.C.	84	O6	92	A9
69	A6	77	O1	85	O7	93	A8
70	A5	78	O2	86	O8	94	A13
71	A4	79	O3	87	CE	95	A14
72	A3	80	Vss	88	A10	96	Vcc

N.C.: Internal connection only. Not for use.

■ PIN DESCRIPTIONS

Pin no.		I/O			
SH-DIP*1 MDIP*2	QFP*3 MQFP*4	LQFP*5 QFP*6	Pin name	circuit type	Function
30	23	22	X0	_	Connecting pins to crystal oscillator circuit or other os-
31	24	23	X1	А	cillator circuit. The X0 pin can connect to an external clock. In that case, X1 is left open.
28	21	20	MOD0	В	Input pins for memory access mode setting.
29	22	21	MOD1		Connect directly to Vss.
27	20	19	RST	С	Reset I/O pin. This pin has pull-up resistance with CMOS I/O or hysteresis input. At an internal reset request, an 'L' signal is output. An 'L' level input initializes the internal circuits.
56 to 49	49 to 42	48 to 41	P00 to P07	D	General purpose I/O ports.
48 to 41	41 to 34	40 to 33	P10 to P17	D	General purpose I/O ports.
40	33	32	P20/PWCK	Е	General purpose I/O port.Resource I/O pin (hysteresis input).Hysteresis input. This pin also functions as a PWC input.
39	32	31	P21/ PPG01	D	General purpose I/O port. This pin also functions as the PPG01 output.
38	31	30	P22/ PPG02	D	General purpose I/O port. This pin also functions as the PPG02 output.
37	30	29	P23	D	General purpose I/O port.
36	29	28	P24	D	General purpose I/O port.
35	28	27	P25	D	General purpose I/O port.
34	27	26	P26	D	General purpose I/O port.
33	26	25	P27	D	General purpose I/O port.
58	51	50	P30/ PPG03/ MCO	D	General purpose I/O port. This pin also functions as the PPG03 output.
59	52	51	P31/SCK1 (UCK1) / LMCO	Е	General purpose I/O port.Resource I/O pin (hysteresis input).This pin also functions as the UART/SIO clock input/output pin.
60	53	52	P32/SO1 (UO1)	D	General purpose I/O port. This pin also functions as the UART/SIO data output pin.
61	54	53	P33/SI1 (UI1)	E	General purpose I/O port.Resource input/output pin (hysteresis input).This pin also functions as the UART/ SIO serial data input pin.
62	55	54	P34/PTO2	D	General purpose I/O port. This pin also functions as the PWM timer 2 output pin.
63	56	55	P35/PWC	Е	General purpose I/O port.Resource I/O pin (hysteresis input).This pin also functions as a PWC input.

Pin no.		Pin I/O			
SH-DIP*1 MDIP*2	QFP*3 MQFP*4	LQFP*5 QFP*6	name	circuit type	Function
1	58	57	P36/ WTO	D	General purpose I/O port.Resource output. This pin also functions as the PWC output pin.
2	59	58	P37/ PTO1	D	General purpose I/O port.Resource output. This pin also functions as the PWM timer 1 output pin.
3	60	59	P40/ INT20/ EC	Е	General purpose I/O port.Resource I/O pin (hysteresis input)This pin also functions as an external interrupt input or 16-bit timer/counter input.
4	61	60	P41/ INT21/ SCK2	E	General purpose I/O port.Resource I/O pin (hysteresis input)This pin also functions as an external interrupt input or SIO clock I/O pin.
5	62	61	P42/ INT22/ SO2/ SDA	G	N-ch open drain output. Resource I/O pin (hysteresis only for INT22 input) . This pin also functions as an external interrupt input, SIO serial data output, or I ² C data line.
6	63	62	P43/ INT23/ SI2/SCL	G	N-ch open drain output. Resource I/O pin (hysteresis only for INT23 input) . This pin also functions as an external interrupt, SIO serial data input, or I ² C clock I/O pin.
7	64	63	P44/ INT24/ UCK2	E	General purpose I/O port. Resource I/O pin (hysteresis input) . This pin also functions as an external interrupt input or UART clock I/O pin.
8	1	64	P45/ INT25/ UO2	E	General purpose I/O port. Resource I/O pin (hysteresis input) . This pin also functions as an external interrupt input or UART data output pin.
9	2	1	P46/ INT26/ UI2	E	General purpose I/O port. Resource I/O pin (hysteresis input) . This pin also functions as an external interrupt input or UART data input pin.
10	3	2	P47/ INT27/ ADST	E	Except MB89F538 General purpose I/O port. Resource I/O pin (hysteresis input) . This pin also functions as an external interrupt input or
		_	MOD2	В	A/D converter clock input pin. MB89F538 Input pins for memory access mode setting. Connect directly to Vss.
11 to 18	4 to 11	3 to 10	P50/AN0 to P57/ AN7	Н	N-ch open drain output port. This pin also functions as an A/D converter analog input pin. (Continued)

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Pin no.		I/O					
SH-DIP*1 MDIP*2	QFP*3 MQFP*4	LQFP*5 QFP*6	Pin name	circuit type	Function		
22 to 24	15 to 17	14 to 16	P60/INT10 to P62/INT12	I	General purpose input port. Resource input pin (hysteresis input) . This pin also functions as an external interrupt input pin.		
25	18	17	P63/INT13	I	Single-clock system	General purpose input port. Resource input (hysteresis input) . This pin also functions as an external interrupt.	
			X0A	А	Dual-clock system	Connected pin for sub clock.	
26	19	18	P64	J	Single-clock system	General purpose input port.	
20	19	10	X1A	А	Dual-clock system	Connected pin for sub clock.	
64	57	56	Vcc	_	Power supply pin.		
32	25	24	Vss		Ground pin (GND) .		
19	12	11	AVcc		A/D converter power sup	ply pin.	
20	13	12	AVR		A/D converter reference	voltage input pin.	
21	14	13	AVss	_	A/D converter power sup Used at the same voltage	ply pin. e level as the Vss supply.	
F7	50	40	0		MB89F538	Capacitor connection pin for stabilization power supply. Connect an external ceramic capacitor of approximately 0.1 µF.	
57	50	49	С		MB89P538	Fixed at Vss.	
					MB89PV530 MB89537A/537AC MB89538A/538AC MB89535A	N.C. pin	

*1: DIP-64P-M01

*2: MDP-64C-P02

*3: FPT-64P-M06

*4: MQP-64C-P01

*5: FPT-64P-M03

*6: FPT-64P-M09

External EPROM Socket Pin Function Descriptions (MB89PV530 only)

External EPROM Socket Pin Function Descriptions (MB89PV530 only)							
	Pin no.		I/O Circuit	Function			
MDIP*1	MQFP*2	Pin name	type				
65	66	A15					
66	67	A12					
67	68	A7					
68	69	A6					
69	70	A5	0	Address output pins.			
70	71	A4		Address output pins.			
71	72	A3					
72	73	A2					
73	74	A1					
74	75	A0					
75	77	O1					
76	78	O2	I	Data input pins			
77	79	O3					
78	80	Vss	0	Power supply pin (GND) .			
79	82	O4					
80	83	O5					
81	84	O6	I	Data input pins.			
82	85	O7					
83	86	O8					
84	87	CE	0	ROM chip enable pin.			
	<u> </u>			Outputs an "H" level signal in standby mode.			
85	88	A10	0	Address output pin.			
86	89	ŌĒ	0	ROM output enable pin.			
			_	Outputs "L" at all times.			
87	91	A11					
88	92	A9	0				
89	93	A8		Address output pins.			
90	94	A13	0				
91	95	A14	0				
92	96	Vcc	0	EPROM power supply pin.			
_	65 76 81 90	N.C.	0	Internally connected. These pins always left open.			

*1 : MDP-64C-P02

*2: MQP-64C-P01

■ I/O CIRCUIT TYPES

Туре	Circuit	Remarks
А	X1 (X1A) Nch Pch X0 (X0A) Nch Pch Nch Pch	Oscillator feedback resistance • High speed side = approx. 1 MΩ • Low speed side = approx. 10 MΩ
В		 Hysteresis input Pull-down resistance built-in to MB89535A MB89537A/537AC MB89538A/538AC
С	R Pch	 Pull-up resistance approx. 50 kΩ Hysteresis input
D	Pull-up control resistor	CMOS I/O Software pull-up resistance can be used. Approx. 50 kΩ
E	Pull-up control resistors	 CMOS I/O Software pull-up resistance can be used. Approx. 50 kΩ
	Port input Resource input	

(Continued) Type	Circuit	Remarks
G	Resource input Port input	 N-ch open drain output Hysteresis input CMOS input
Н	Pch Nch Analog input	N-ch open drain output Analog input (A/D converter)
ı	Pull-up control resistors Resource Port	 Hysteresis input CMOS input Software pull-up resistance can be used. Approx. 50 kΩ
J	Pull-up control resistors Port	CMOS input Software pull-up resistance can be used. Approx. 50 kΩ

HANDLING DEVICES

1.Preventing Latchup

Care must be taken to ensure that maximum voltage ratings are not exceeded (to prevent latchup). When CMOS integrated circuit devices are subjected to applied voltages higher than Vcc at input and output pins (other than medium- and high-withstand voltage pins), or to voltages lower than Vss, as well as when voltages in excess of rated levels are applied between Vcc and Vss, the phenomenon known as latchup can occur.

When a latchup condition occurs, supply current can increase dramatically and may destroy semiconductor elements. In using semiconductor devices, always take sufficient care to avoid exceeding maximum ratings.

Also when switching power on or off to analog systems, care must be taken that analog power supplies (AVcc, AVR) and analog input signals do not exceed the level of the digital power supply.

2. Power Supply Voltage Fluctuations

Even within the warranted operating range of the Vcc supply voltage, sudden changes in supply voltage can cause abnormal operation. As a measure for stability, it is recommended that the Vcc ripple fluctuation (peak to peak value) should be kept within 10% of the reference Vcc value on commercial power supply (50 Hz-60 Hz), and instantaneous voltage fluctuations such as at power-on and shutdown should be kept within a transient variability limit of 0.1V/ms.

3. Treatment of Unused Input Pins

If unused input pins are left open, abnormal operation may result. Any unused input pins should be connected to pull-up or pull-down resistance.

4. Treatment of N.C. Pins

Any pins marked 'NC' (not connected) must be left open.

5. Treatment of Power Supply Pins on Models with Built-in A/D Converter

Even when A/D converters are not in use, pins should be connected so that AVcc = Vcc, and AVss = AVR = Vss.

6. Precautions for Use of External Clock

Even when an external clock signal is used, an oscillator stabilization wait period is used after a power-on reset, or escape from sub clock mode or stop mode.

7. Execution of Programs on RAM

Debugging of programs executed on RAM cannot be performed even when using the MB89PV530.

8. Wild Register Functions

Wild registers cannot be debugged with the MB89PV530 and tools. To verify operations, actual in-device testing on the MB89P538 or MB89F538 is advised.

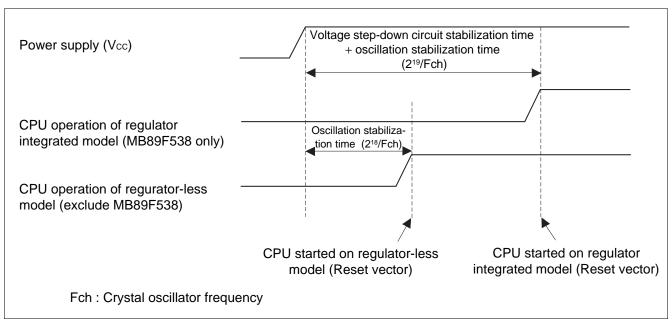
9. Details on handling the C terminal of the MB89530 series

The MB89530 series contains the following products. The regulator integrated model and the regulator-less model have different performance characteristics.

Part No.	Operation Voltage	integrated model	Terminal type	Terminal treatments	
MB89PV530		Not included	N.C terminal	Not required	
MD00DE20	2.7 V to 5.5 V	Included		Fixed to Vcc	
MB89P538		Not included	C terminal	Fixed to Vss	
MB89F538	3.5 V to 5.5 V	Included		0.1 μF capacitor connected	
MB89537A/537AC					
MB89538A/538AC	2.2 V to 5.5 V	Not included	N.C terminal	Not required	
MB89535A					

Although these product models have the same internal resources, the operation sequence after a power-on reset is different between the regulator integrated model and regulator-less model.

The operation sequence after a power-on reset of each model is shown below.



As avobe, the regulator integrated model starts the CPU behind the regulator-less model. This is because the regulator requires a settling time for normal operation.

The MB89P538 offers a choice of regulator-integrated and regulator-less models selectable depending on the C-terminal treatment. Use the right one for your mask board.

10. Note to Noise in the External Reset Pin (RST)

If the reset pulse applied to the external reset pin (\overline{RST}) does not meet the specifications, it may cause malfunctions. Use caution so that the reset pulse less than the specifications will not be fed to the external reset pin (\overline{RST}) .

■ PROGRAMMING AND ERASING FLASH MEMORY ON THE MB89F538

1. Flash Memory

The flash memory is located between 4000_H and FFFF_H in the CPU memory map and incorporates a flash memory interface circuit that allows read access and program access from the CPU to be performed in the same way as mask ROM. Programming and erasing flash memory is also performed via the flash memory interface circuit by executing instructions in the CPU. This enables the flash memory to be updated in place under the control of the CPU, providing an efficient method of updating program and data.

2. Flash Memory Features

- 48 K byte × 8-bit configuration (16 K + 8 K + 8 K + 16 K sectors)
- Automatic programming algorithm (Embedded algorithm*: Equivalent to MBM29LV200)
- Includes an erase pause and restart function
- Data polling and toggle bit for detection of program/erase completion
- Detection of program/erase completion via CPU interrupt
- Compatible with JEDEC-standard commands
- Sector Protection (sectors can be combined in any combination)
- No. of program/erase cycles: 10,000 (Min)
- *: Embedded Algorithm is a trademark of Advanced Micro Devices.

3. Procedure for Programming and Erasing Flash Memory

Programming and reading flash memory cannot be performed at the same time. Accordingly, to program or erase flash memory, the program must first be copied from flash memory to RAM so that programming can be performed without program access from flash memory.

4. Flash Memory Register

Control status register (FMCS)

Address	bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0	Initial value
007Ан	INTE	RDYINT	WE	RDY	Reserved	Reserved	_	Reserved	000Х00-0в
	R/W	R/W	R/W	R	R/W	R/W	_	R/W	

5. Sector Configuration

The table below shows the sector configuration of flash memory and lists the addresses of each sector for both during CPU access a flash memory programming.

· Sector configuration of flash memory

Flash Memory	CPU Address	Programmer Address*					
16 K bytes	FFFFH to C000H	1FFFFн to 1C000н					
8 K bytes	BFFF _H to A000 _H	1BFFFн to 1A000н					
8 K bytes	9FFFн to 8000н	19FFFн to 18000н					
16 K bytes	7FFFн to 4000н	17FFFн to 14000н					

*: Programmer address

The programmer address is the address to be used instead of the CPU address when programming data from a parallel flash memory programmer. Use the programmer address on programming or erasing using a general-purpose parallel programmer.

6. ROM Programmer Adaptor and Recommended ROM Programmers

Part number	Package	Adaptor Part No.	Recommended Programmer Manufacturer and Model
		Sunhayato Corp.	Ando Electric Co. Ltd.
MB89F538-101PF MB89F538-201PF	FPT-64P-M06	FLASH-64QF-32DP-8LF	
MB89F538-101PFM MB89F538-201PFM	FPT-64P-M09	FLASH-64QF2-32DP-8LF2	AF9708* AF9709*
MB89F538-101P-SH MB89F538-201P-SH	DIP-64P-M01	FLASH-64SD-32DP-8LF	

^{*:} For the version of the programmer, contact the Flash Support Group, Inc.

• Enquiries

Sunhayato Corp. : TEL : +81-3-3984-7791

FAX: +81-3-3971-0535

E-mail: adapter@sunhayato.co.jp

Flash Support Group, Inc.: FAX: +81-53-428-8377

E-mail: support@j-fsg.co.jp

■ ONE-TIME WRITING SPECIFICATIONS WITH PROM AND EPROM MICROCONTROLLERS

The MB89P538 has a PROM mode with functions equivalent to the MBM27C1001, allowing writing with a general purpose ROM writer using a proprietary adapter. Note, however, that the use of electronic signature mode is not supported.

ROM writer adapters

With some ROM writers, stability of writing performance is enhanced by placing an 0.1μF capacitor between the Vcc and Vss pins. The following table lists adapters for use with ROM writers.

ROM Writer Adapters

Part number	Package	Compatible adapter		
MB89P538-101PF MB89P538-201PF	FPT-64P-M06	ROM-64QF-32DP-8LA2*		
MB89P538-101PFM MB89P538-201PFM	FPT-64P-M09	ROM-64QF2-32DP-8LA		
MB89P538-101P-SH MB89P538-201P-SH	DIP-64P-M01	ROM-64SD-32DP-8LA2*		

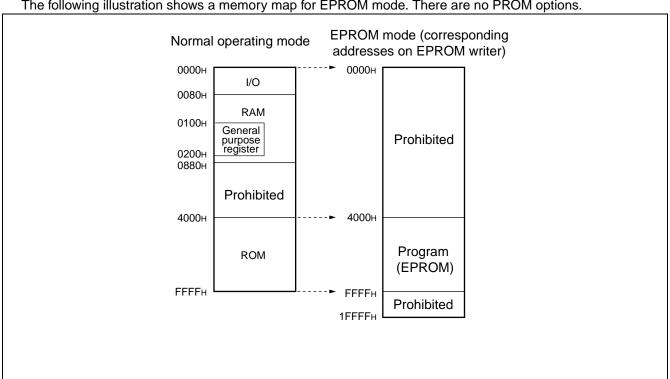
Inquiries should be addressed to Sunhayato Corp.: TEL: +81-3-3984-7791

FAX : +81-3-5396-9106

E-mail: adapter@sunhayato.co.jp

• Memory map for EPROM mode

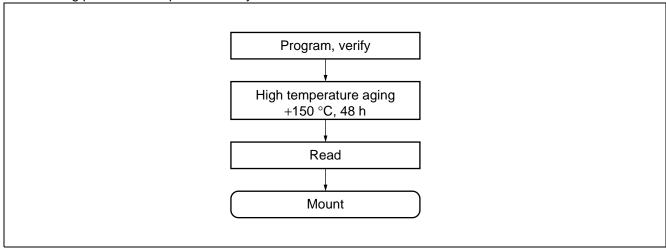
The following illustration shows a memory map for EPROM mode. There are no PROM options.



^{*:} Version 3 or later should be used.

• Recommended screening conditions

Before one-time writing of microcontroller programs to PROM, high temperature aging is recommended as a screening process for chips before they are mounted.



• About writing yields

The nature of chips before one-time writing of microcontroller programs to PROM prevents the use of all-bit writing tests. Therefore it is not possible to guarantee writing yields of 100% in some cases.

■ EPROM WRITING TO PIGGY-BACK/EVALUATION CHIPS

This section describes methods of writing to EPROM on piggy-back/evaluation chips.

• EPROM model

MBM27C512-20TV

• Writer adapter

For writing to EPROM using a ROM writer, use one of the writer adapters shown below (manufactured by Sunhayato Corp.) .

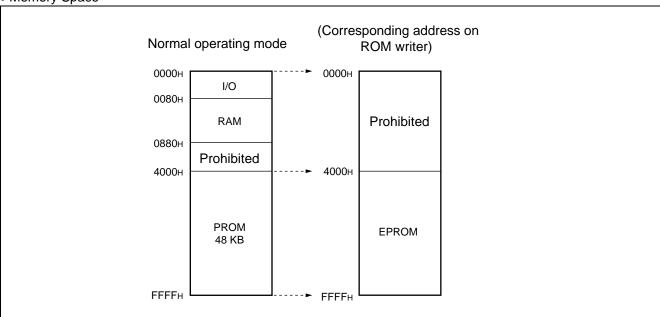
Package	Adapter socket model
LCC-32 (rectangular)	ROM-32LC-28DP-YG

Inquiries should be addressed to Sunhayato Corp. : TEL : +81-3-3984-7791

FAX : +81-3-3971-0535

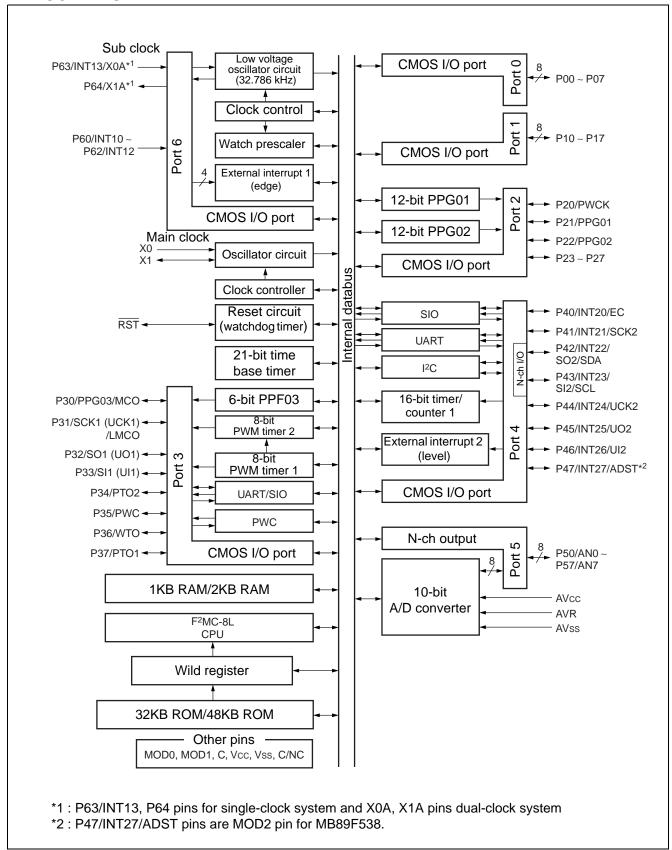
E-mail: adapter@sunhayato.co.jp

Memory Space



- Writing to EPROM
 - 1) Set up the EPROM writer for the MBM27C512.
 - 2) Load program data to the ERPOM writer, in the area 4000H FFFFH.
 - 3) Use the EPROM writer to write to the area 4000_H FFFF_H.

■ BLOCK DIAGRAM

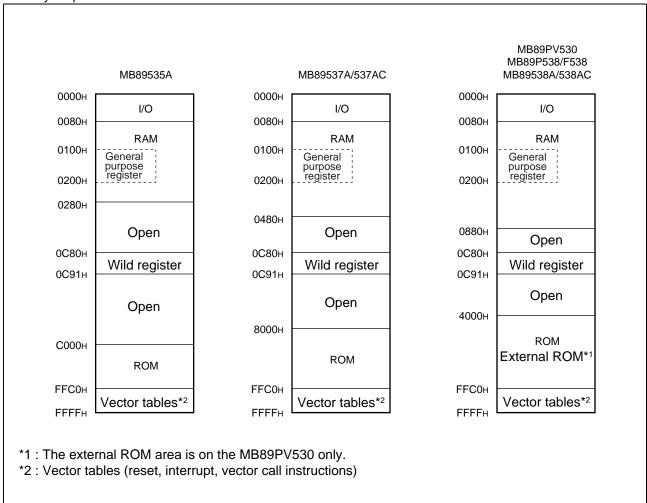


■ CPU CORE

1. Memory Space

The MB89530A series has 64 KB of memory space, containing all I/O, data areas, and program areas. The I/O area is located at the lowest addresses, with the data area placed immediately above. The data area can be partitioned into register areas, stack areas, or direct access areas depending on the application. The program area is located at the opposite end of memory, closest to the highest addresses, and the highest part of this area is assigned to the tables of interrupt and reset vectors and vector call instructions. The following diagram shows the structure of memory space in the MB89530A series.

Memory Map



2. Registers

The F²MC-8L series has two types of registers, dedicated-use registers within the CPU, and general-purpose registers in memory.

Program counter (PC) : 16-bit length, shows the location where instructions are stored.

Accumulator (A) : 16-bit length, a temporary memory register for calculation operations.

The lower byte is used for 8-bit data processing instructions.

Temporary accumulator (T) : 16-bit length, performs calculations with the accumulator.

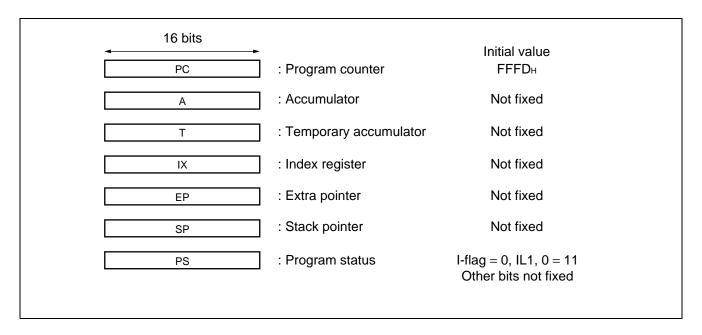
The lower byte is used for 8-bit data processing instructions.

Index register (IX) : 16-bit length, a register for index modification.

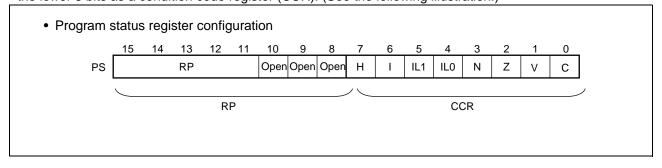
Extra pointer (EP) : 16-bit length, a pointer indicating memory addresses.

Stack pointer (SP) : 16-bit length, indicates stack areas.

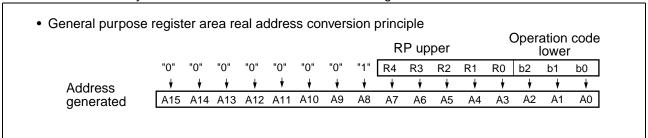
Program status (PS) : 16-bit length, contains register pointer and condition code.



In addition, the PS register can be divided so that the upper 8 bits are used as a register bank pointer (RP), and the lower 8 bits as a condition code register (CCR). (See the following illustration.)



The RP register shows the address of the register bank currently being used, so that the RP value and the actual address are related by the conversion rule shown in the following illustration.



The CCR register has bits that show the content of results of calculations and transferred data, and bits that control CPU operation during interrupts.

H-flag : Set to 1 if calculations result in carry or borrow operations from bit 3 to bit 4, otherwise set to 0.

This flag is used for decimal correction instructions.

I-flag : This flag is set to 1 if interrupts are enabled, and 0 if interrupts are prohibited.

The default value at reset is 0.

IL1, 0 : Indicates the level of the currently permitted interrupts.

Only interrupt requests having a more powerful level than the value of these bits will be processed.

IL1	IL0	Interrupt level	Strength
0	0	1	Strong
0	1	l	†
1	0	2	
1	1	3	Weak

N-flag : Set to 1 if the highest bit is 1 after a calculation, otherwise cleared to 0.

Z-flag : Set to 1 if a calculation result is 0, otherwise cleared to 0.

V-flag : Set to 1 if a two's complement overflow results during a calculation, otherwise cleared to 0.

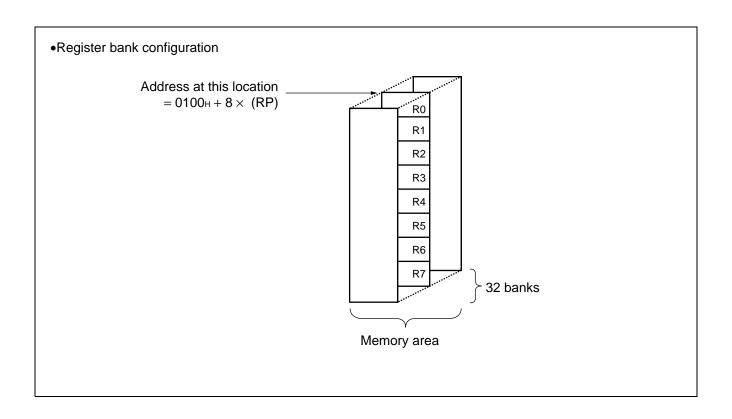
C-flag : Set to 1 if a calculation results in a carry or borrow operation from bit 7, otherwise cleared to 0.

This is also the shift-out value in a shift instruction.

In addition, the following general purpose registers are available.

General purpose registers: 8-bit length, used to contain data.

The general purpose registers are 8-bit registers located in memory. There are eight such registers per bank, and the MB89530A series have up to 32 banks for use. The bank currently in use is indicated by the register bank pointer (RP).



■ I/O MAP

Address	Register name	Register description	Write/Read	Initial value
00н	PDR0	Port 0 data register	R/W	XXXXXXXX
01н	DDR0	Port 0 direction register	W	0000000
02н	PDR1	Port 1 data register	R/W	XXXXXXXX
03н	DDR1	Port 1 direction register	W	0000000B
04н to 06н		(Reserved area)		
07н	SYCC	System clock control register	R/W	Х-1 ММ1 0 Ов
08н	STBC	Standby control register	R/W	00010в
09н	WDTC	Watchdog control register	R/W	0XXXX _B
ОАн	TBTC	Time base timer control register	R/W	00000в
0Вн	WPCR	Watch prescaler control register	R/W	000000в
0Сн	PDR2	Port 2 data register	R/W	XXXXXXXX
0Дн	DDR2	Port 2 direction register	R/W	0000000
0Ен	PDR3	Port 3 data register	R/W	XXXXXXXX
0Fн	DDR3	Port 3 direction register	R/W	0000000
10н	PDR4	Port 4 data register	R/W	XXXX 1 1 XX _B
11н	DDR4	Port 4 direction register	R/W	000000в
12н	PDR5	Port 5 data register	R/W	11111111
13н	PDR6	Port 6 data register	R	XXXXXXXX
14н to 21н		(Reserved area)		
22н	SMC11	Serial mode control register 1 (UART)	R/W	0000000B
23н	SRC1	Serial rate control register (UART)	R/W	011000в
24н	SSD1	Serial status and data register (UART)	R/W	00100-1X _B
25н	SIDR1/ SODR1	Serial input/output data register (UART)	R/W	XXXXXXXX
26н	SMC12	Serial mode control register 2 (UART)	R/W	100001в
27н	CNTR1	PWM control register 1	R/W	0000000
28н	CNTR2	PWM control register 2	R/W	000-0000в
29н	CNTR3	PWM control register 3	R/W	-000в
2Ан	COMR1	PWM compare register 1	W	XXXXXXXX
2Вн	COMR2	PWM compare register 2	W	XXXXXXXX
2Сн	PCR1	PWC pulse width control register 1	R/W	000000в
2Dн	PCR2	PWC pulse width control register 2	R/W	0000000
2Ен	RLBR	PWC reload buffer register	R/W	XXXXXXXX
2Fн	SMC21	Serial mode control register 1 (UART/SIO)	R/W	00000000
30н	SMC22	Serial mode control register 2 (UART/SIO)	R/W	0000000
31н	SSD2	Serial status and data register (UART/SIO)	R/W	00001в
32н	SIDR2/ SODR2	Serial data register (UART/SIO)	R/W	XXXXXXXXB
33н	SRC2	Baud rate generator reload register	R/W	XXXXXXXX

Address	Register name	Register description	Write/Read	Initial value
34н	ADC1	A/D control register 1	R/W	00000-0в
35н	ADC2	A/D control register 2	R/W	-0000001в
36н	ADDL	A/D data register low	R/W	XXXXXXXX
37н	ADDH	A/D data register high	R/W	0 Ов
38н	PPGC2	PPG2 control register (12-bit PPG)	R/W	00000000B
39н	PRL22	PPG2 reload register 2 (12-bit PPG)	R/W	0Х000000
3Ан	PRL21	PPG2 reload register 1 (12-bit PPG)	R/W	ХХ000000
3Вн	PRL23	PPG2 reload register 3 (12-bit PPG)	R/W	ХХ000000
3Сн	TMCR	16-bit timer control register	R/W	000000B
3Dн	TCHR	16-bit timer counter register high	R/W	00000000
3Ен	TCLR	16-bit timer counter register low	R/W	00000000
3Fн	EIC1	External interrupt 1 control register 1	R/W	00000000
40н	EIC2	External interrupt 1 control register 2	R/W	00000000
41н to 48н		(Reserved area)		I
49н	DDCR	DDC select register	R/W	Ов
4Aн to 4Вн		(Reserved area)		I
4Сн	PPGC1	PPG1 control register (12-bit PPG)	R/W	0000000B
4Dн	PRL12	PPG1 reload register 2 (12-bit PPG)	R/W	0Х000000
4Ен	PRL11	PPG1 reload register 1 (12-bit PPG)	R/W	ХХ000000
4 Fн	PRL13	PPG1 reload register 3 (12-bit PPG)	R/W	ХХ000000
50н	IACR	I ² C address control register	R/W	0 0 Ов
51н	IBSR	I ² C bus status register	R	0000000B
52н	IBCR	I ² C bus control register	R/W	0000000B
53н	ICCR	I ² C clock control register	R/W	000XXXXXB
54н	IADR	I ² C address register	R/W	-XXXXXXXB
55н	IDAR	I ² C data register	R/W	XXXXXXXX
56н	EIE2	External interrupt 2 control register	R/W	00000000
57н	EIF2	External interrupt 2 flag register	R/W	Ов
58н	RCR1	6-bit PPG control register 1	R/W	0000000B
59н	RCR2	6-bit PPG control register 2	R/W	0Х000000
5Ан	CKR	Clock output control register	R/W	0 Ов
5Вн to 6Fн		(Reserved area)	1	1
70н	SMR	Serial mode register (SIO)	R/W	0000000B
71н	SDR	Serial data register (SIO)	R/W	XXXXXXXX
72н	PURR0	Port 0 pull-up resistance register	R/W	11111111
73н	PURR1	Port 1 pull-up resistance register	R/W	11111111
74н	PURR2	Port 2 pull-up resistance register	R/W	11111111
75н	PURR3	Port 3 pull-up resistance register	R/W	11111111
76н	PURR4	Port 4 pull-up resistance register	R/W	111111в
77н	WREN	Wild register enable register	R/W	000000в

(Continued)

Address	Register name	Register description	Write/Read	Initial value
78н	WROR	Wild register data test register	R/W	000000B
79н	PURR6	Port 6 pull-up resistance register	R/W	111111в
7Ан	FMCS	Flash memory control status resister	R/W	00000-0
7Вн	ILR1	Interrupt level setting register 1	W	11111111
7Сн	ILR2	Interrupt level setting register 2	W	11111111
7Dн	ILR3	Interrupt level setting register 3	W	11111111
7Е н	ILR4	Interrupt level setting register 4	W	11111111
7F ⊦	ITR	Interrupt test register	Access prohibited	XXXXXXX 0 0 _B
С80н	WRARH1	Upper address setting register 1	R/W	XXXXXXXX
С81н	WRARL1	Lower address setting register 1	R/W	XXXXXXXX
С82н	WRDR1	Data setting register 1	R/W	XXXXXXXX
С83н	WRARH2	Upper address setting register 2	R/W	XXXXXXXX
С84н	WRARL2	Lower address setting register 2	R/W	XXXXXXXX
С85н	WRDR2	Data setting register 2	R/W	XXXXXXXX
С86н	WRARH3	Upper address setting register 3	R/W	XXXXXXXX
С87н	WRARL3	Lower address setting register 3	R/W	XXXXXXXX
С88н	WRDR3	Data setting register 3	R/W	XXXXXXXX
С89н	WRARH4	Upper address setting register 4	R/W	XXXXXXX
С8Ан	WRARL4	Lower address setting register 4	R/W	XXXXXXX
С8Вн	WRDR4	Data setting register 4	R/W	XXXXXXX
С8Сн	WRARH5	Upper address setting register 5	R/W	XXXXXXX
C8D _H	WRARL5	Lower address setting register 5	R/W	XXXXXXX
С8Ен	WRDR5	Data setting register 5	R/W	XXXXXXXX
С8Fн	WRARH6	Upper address setting register 6 R/W		XXXXXXXX
С90н	WRARL6	Lower address setting register 6	R/W	XXXXXXXX
С91н	WRDR6	Data setting register 6	R/W	XXXXXXXX

• Description of write/read symbols :

R/W: read/write enabled

R : Read only W : Write only

• Description of initial values :

0 : This bit initialized to "0".1 : This bit initialized to "1".

X : The initial value of this bit is not determined.M : The initial value of this bit is a mask option.

- : This bit is not used.

Note: Do not use reserved spaces.

■ ELECTRICAL CHARACTERISTICS

1. Absolute Maximum Ratings

(AVss = Vss = 0 V)

Parameter	Symbol	Rat	ing	Unit	Remarks	
Parameter	Syllibol	Min	Max	Offic	Remarks	
Supply voltage	Vcc, AVcc	Vss - 0.3	Vss + 6.0	V	MB89535A/537A/538A* MB89537AC/538AC	
o apply some	AVR	Vss - 0.3	Vss + 6.0	V	MB89F538/P538 MB89PV530	
Input voltage	Vı	Vss - 0.3	Vcc + 0.3	V	Other than P42, P43	
Input voltage	VI	Vss - 0.3	Vss + 6.0	V	P42, P43	
Output voltage	Vo	Vss - 0.3	Vcc + 0.3	V	Other than P42, P43	
Output voltage	VO	Vss - 0.3	Vss + 6.0	V	P42, P43	
"L" level maximum output current	loL	_	15	mA		
"L" level average output current	lolav	_	4	mA	Average value (operating current × operating duty)	
"L" level maximum total output current	ΣΙοι	_	100	mA		
"L" level average total output current	Σ lolav	_	40	mA	Average value (operating current × operating duty)	
"H" level maximum output current	Іон	_	-15	mA		
"H" level average output current	Іонаv	_	-4	mA	Average value (operating current × operating duty)	
"H" level maximum total output current	Σ Іон	_	-50	mA		
"H" level average total output current	Σ lohav	_	-20	mA	Average value (operating current × operating duty)	
Current consumption	P□	_	300	mW		
Operating temperature	TA	-40	+85	°C		
Storage temperature	Tstg	-55	+150	°C		

^{*:} AVcc and Vcc are to be used at the same potential. AVR should not exceed AVcc + 0.3V.

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

2. Recommended Operating Conditions

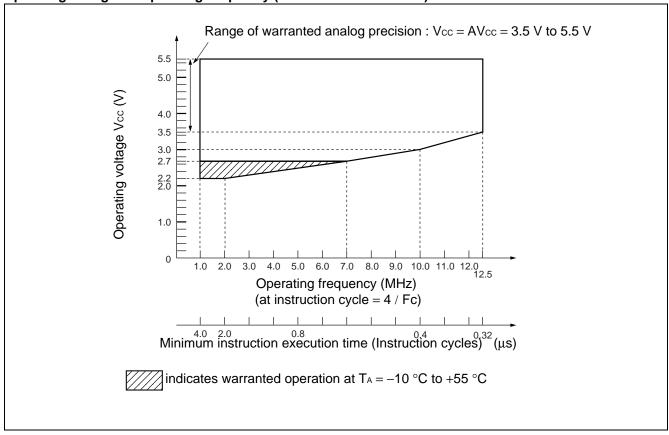
(AVss = Vss = 0 V)

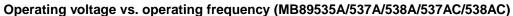
Parameter	Symbol	Val	lue	Unit	Remarks		
rarameter	Зуппоот	Min	Max	Oilit			
	Vcc, AVcc	2.2*	5.5	V	Range warranted for normal operation	MB89535A MB89537A/538A	
		1.5	5.5	V	RAM status in stop mode	MB89537AC/ 538AC	
		2.7*	5.5	V	Range warranted for normal operation	MB89P538	
Supply voltage		1.5	5.5	V	RAM status in stop mode	MB89PV530	
		3.5	5.5	V	Range warranted for normal operation	- MB89F538	
		3.0	5.5	V	RAM status in stop mode	- INIDOSE 330	
	AVR	3.5	AVcc	V			
Operating temperature	Та	-40	+85	°C			

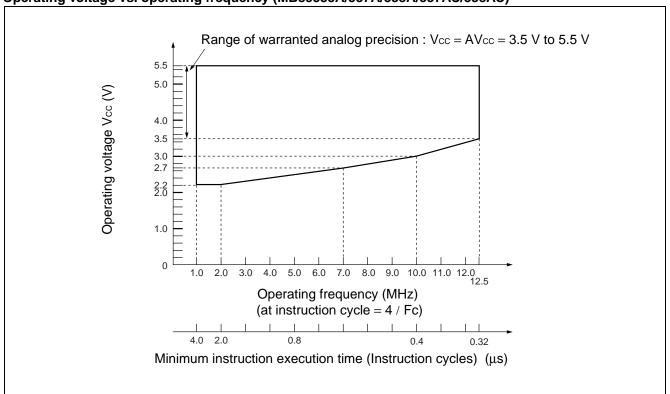
^{*:} Varies according to frequency used, and instruction cycle.

See "Operating voltage vs. operating frequency" and "5. A/D Converter Electrical Characteristics".

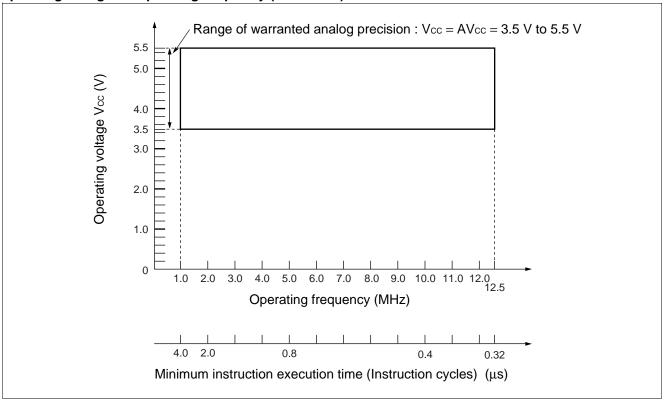








Operating voltage vs. operating frequency (MB89F538)



WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

3. DC Characteristics

(1) Supply Voltage at 5.0 (V)

(AVcc = Vcc = 5.0 V, AVss = Vss = 0 V, $T_A = -40$ °C to +85 °C)

Parameter	Symbol	Pin name	Condition	Value				
				Min	Тур	Max	Unit	Remarks
"H" level input voltage	VIH	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P60 to P64, SI1, SI2	_	0.7 Vcc	_	Vcc + 0.3	٧	
	Vihs	RST, MOD0, MOD1, INT20 to INT27, UCK1, UI1, INT10 to INT13, SCK1, EC, PWCK, PWC, SCK2, UCK2, UI2, ADST	_	0.8 Vcc		Vcc + 0.3	٧	
	VIHSMB	-SCL, SDA	_	Vss + 1.4		Vss + 5.5	٧	With SMB input buffer selected*
	V _{IHI2C}		_	0.7 Vcc		Vss + 5.5	V	With I ² C input buffer selected*
"L" level input voltage	VıL	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P60 to P64, SI1, SI2	_	Vss - 0.3		0.3 Vcc	V	
	VILS	RST, MOD0, MOD1, INT20 to INT27, UCK1, UI1, INT10 to INT13, SCK1, EC, PWCK, PWC, SCK2, UCK2, UI2, ADST	_	Vss - 0.3	_	0.2 Vcc	V	
	VILSMB	-SCL, SDA	_	Vss - 0.3	_	Vss + 0.6	V	With SMB input buffer selected*
	V _{ILI2C}		_	Vss - 0.3	_	0.3 Vcc	V	With I ² C input buffer selected*
Open drain output applied voltage	V _{D1}	P50 to P57 P42, P43	_	Vss - 0.3	_	Vcc + 0.3	V	
	V _{D2}					Vss + 5.5	٧	
"H" level output voltage	Vон	P00 to P07, P10 to P17, P20 to P24, P30 to P37, P40, P41, P44 to P47	Iон = -2.0 mA	4.0	_	_	V	
		P25 to P27	Iон = -3.0 mA					
"L" level output voltage	Vol	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, RST	loL = 4.0 mA	_	_	0.4	V	

(Continued)

(AVcc = Vcc = 5.0 V, AVss = Vss = 0 V, $T_A = -40$ °C to +85 °C)

Parameter	Symbol	Pin name		Value				
			Condition	Min	Тур	Max	Unit	Remarks
Input leak current (Hi-Z output leak current)	lu	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P64	0.0 V < V _I < V _{CC}	-5	_	+5	μΑ	With no pull-up resistance specified
Open drain output leak current	Інор	P42, P43	0.0 V < V _I < V _{SS} + 5.5 V		_	+5	μА	
Pull-up resistance	Rpull	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40, P41, P44 to P47, P60 to P64, RST	Vı = 0.0 V	25	40	100	kΩ	With pull-up resistance specified. The RST signal is excluded.
Supply current	Icc1	Vcc	$F_{\text{CH}} = 10.0 \text{ MHz}$ $V_{\text{CC}} = 5.0 \text{ V}$ $t_{\text{inst}} = 0.4 \mu\text{s}$		15	20	mA	MB89P538/ PV530
				_	6	10	mA	MB89F538
					8	13	mA	MB89535A/7A/8A MB89537AC/ 538AC
	Icc2		$F_{\text{CH}} = 10.0 \text{ MHz}$ $V_{\text{CC}} = 5.0 \text{ V}$ $t_{\text{inst}} = 6.4 \mu\text{s}$		5	8.5	mA	MB89P538/ PV530
				_	1.5	3	mA	MB89F538
					1.5	3	mA	MB89535A/7A/8A MB89537AC/ 538AC
	lccs ₁		$F_{\text{CH}} = 10.0 \text{MHz}$ $V_{\text{CC}} = 5.0 \text{V}$ $t_{\text{inst}} = 0.4 \mu \text{s}$		5	7	mA	Sleep mode MB89P538/ PV530
					3	5	mA	Sleep mode MB89F538
				_	2.5	5	mA	Sleep mode MB89535A/7A/8A MB89537AC/ 538AC
	lccs2		$F_{\text{CH}} = 10.0 \text{MHz}$ $V_{\text{CC}} = 5.0 \text{V}$ $t_{\text{inst}} = 6.4 \mu \text{s}$		1.5	3	mA	Sleep mode MB89P538/ PV530
				_	1	2	mA	Sleep mode MB89F538
				_	1	2	mA	Sleep mode MB89535A/7A/8A MB89537AC/ 538AC

(Continued)

(Continued)

(AVcc = Vcc = 5.0 V, AVss = Vss = 0 V, $T_A = -40 \, ^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$)

Parameter	Symbol	Pin name	Condition		Value		Unit	Remarks
Parameter	Syllibol	Pili liaille	Condition	Min	Тур	Max	Offic	Remarks
			_		3	7	mA	Sub mode MB89P538/ PV530
	Iccl		F _{CL} = 32.768 kHz V _{CC} = 5.0 V		400	800	μΑ	Sub mode MB89F538
			T _A = +25 °C		50	85	μΑ	Sub mode MB89535A/7A/8A MB89537AC/ 538AC
			FcL = 32.768 kHz Vcc = 5.0 V TA = +25 °C		30	50	μΑ	Sub, sleep mode MB89P538/ PV530
Supply current	Iccls			_	15	30	μА	Sub, sleep mode MB89F538
					15	30	μΑ	Sub, sleep mode MB89535A/7A/8A MB89537AC/ 538AC
	Ісст		FcL = 32.768 kHz Vcc = 5.0 V T _A = +25 °C	_	5	15	μΑ	Watch mode, main stop
	Іссн		T _A = +25 °C		3	10	μΑ	Sub, stop modes
	la	AVcc	F _{CH} = 10.0 MHz		4	6	mA	A/D conversion running
	Іан		T _A = +25 °C	_	1	5	μΑ	A/D stopped
Input capacitance	Cin	Except Vcc, Vss, AVcc, AVss	f = 1 MHz		5	15	pF	

^{*:} The MB89PV530/P538/537AC/538AC have a built-in I²C function, and a choice of input buffers by software setting. MB89535A/537A/538A have no built-in I2C functions, and therefore this standard does not apply.

(2) Supply Voltage at 3.0 (V) (except MB89F538)

 $(AVcc = Vcc = 3.0 \text{ V}, AVss = Vss = 0 \text{ V}, T_A = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C})$

		D:	,		Value	•		
Parameter	Symbol	Pin name	Condition	Min	Тур	Max	Unit	Remarks
	Vін	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P60 to P64, SI1, SI2	_	0.7 Vcc		Vcc + 0.3	V	
"H" level input voltage	Vihs	RST, MOD0, MOD1, INT20 to INT27, UCK1, UI1, INT10 to INT13, SCK1, EC, PWCK, PWC, SCK2, UCK2, UI2, ADST	_	0.8 Vcc	_	Vcc + 0.3	V	
	VIHSMB	SCL, SDA	_	Vss + 1.4	_	Vss + 5.5	V	With SMB input buffer selected*
V _{IHI2C}	V _{IHI2C}	GOL, SDA	_	0.7 Vcc	_	Vss + 5.5	V	With I ² C input buffer selected*
VıL	VıL	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P60 to P64, SI1, SI2	_	Vss - 0.3	_	0.3 Vcc	V	
"L" level input voltage	VILS	RST, MOD0, MOD1, INT20 to INT27, UCK1, UI1, INT10 to INT13, SCK1, EC, PWCK, PWC, SCK2, UCK2, UI2, ADST	_	Vss - 0.3	_	0.2 Vcc	V	
	VILSMB	eci en	_	Vss - 0.3		Vss + 0.6	V	With SMB input buffer selected*
	V _{ILI2C}	SCL, SDA	_	Vss - 0.3	_	0.3 Vcc	V	With I ² C input buffer selected*
Open drain	V _{D1}	P50 to P57				Vcc + 0.3	V	
output applied voltage	V _{D2}	P42, P43	_	Vss - 0.3	_	Vss + 5.5	V	
"H" level output voltage	Vон	P00 to P07, P10 to P17, P20 to P24, P30 to P37, P40, P41, P44 to P47		2.4	_	_	V	
		P25 to P27	$I_{OH} = -3.0 \text{ mA}$					
"L" level output voltage	Vol	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, RST	IoL = 4.0 mA	_		0.4	V	

(Continued)

 $(AVcc = Vcc = 3.0 \text{ V}, \text{ AVss} = \text{Vss} = 0 \text{ V}, \text{ T}_{A} = -40 \text{ °C to } +85 \text{ °C})$

Parameter	r Symbol Pin name		Condition		Value		Unit	Remarks
i arameter	Symbol	i iii iiaiiie	Condition	Min	Тур	Max	Oilit	Remarks
Input leak current (Hi-Z output leak current)	lu	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P64		-5		+5	μΑ	With no pull-up resistance specified
Open drain output leak current	Іпор	P42, P43	0.0 V < V _I < V _{SS} + 5.5 V		_	+5	μА	
Pull-up resistance	Rpull	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40, P41, P44 to P47, P60 to P64, RST	Vı = 0.0 V	25	70	100	kΩ	With pull-up resistance specified. The RST signal is excluded.
	Icc1		$F_{CH} = 10.0 \; MHz \\ t_{inst} = 0.4 \; \mu s$		6	10	mA	
	Icc2		$F_{\text{CH}} = 10.0 \; MHz \\ t_{\text{inst}} = 6.4 \; \mu s$		1.5	3	mA	
	Iccs ₁		$F_{CH} = 10.0 \; MHz \\ t_{inst} = 0.4 \; \mu s$		2	4	mA	Sleep mode
	Iccs ₂		$F_{\text{CH}} = 10.0 \; MHz \\ t_{\text{inst}} = 6.4 \; \mu s$		1	2	mA	Sleep mode
			FcL =		1	3	mA	Sub modes MB89P538/ PV530
Supply current	IccL	Vcc	32.768 kHz Vcc = 3.0 V T _A = +25 °C	_	20	50	μА	Sub modes MB89535A/7A/ 8A MB89537AC/ 538AC
	Iccls		FcL = 32.768 kHz Vcc = 3.0 V T _A = +25 °C	_	15	30	μА	Sub, sleep modes
	Ісст		F _{CL} = 32.768 kHz V _{CC} = 3.0 V T _A = +25 °C	_	5	15	μΑ	Watch mode, main stop
	Іссн		T _A = +25 °C	_	1	5	μΑ	Sub, stop modes
	la	AVcc	FcH = 10.0 MHz		1	3	mA	A/D conversion running
	Іан		T _A = +25 °C		1	5	μΑ	A/D stopped
Input capaci- tance	Cin	Except Vcc, Vss, AVcc, AVss	f = 1 MHz		5	15	pF	

^{*:} The MB89PV530/P538/537AC/538AC have a built-in I²C function, and a choice of input buffers by software setting. MB89535A/537A/538A have no built-in I2C functions, and therefore this standard does not apply.

4. AC Characteristics

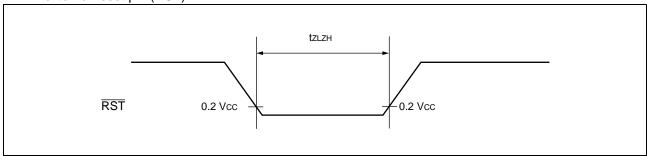
(1) Reset Timing

(Vcc = 5.0 V, AVss = Vss = 0 V,
$$T_A = -40 \, ^{\circ}\text{C}$$
 to +85 $^{\circ}\text{C}$)

Parameter	Svmbol	Condition	Value		Unit	Remarks
	Syllibol	Condition	Min	Max	Offic	Nemarks
RST "L" pulse width	t zlzh	_	48 theyl	_	ns	

Notes: • the main clock oscillator period.

• If the reset pulse applied to the external reset pin (RST) does not meet the specifications, it may cause malfunctions. Use caution so that the reset pulse less than the specifications will not be fed to the external reset pin (RST).

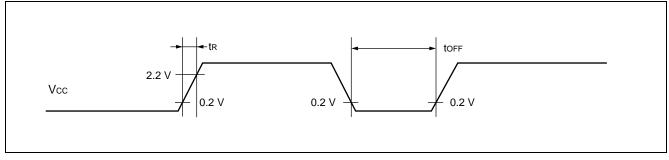


(2) Power-on Reset

(AVss = Vss = 0 V,
$$T_A = -40$$
 °C to +85 °C)

Parameter	Symbol Condition		Va	lue	l lni4	Domorko
	Symbol	Condition	Min	Max	Unit	Remarks
Power on time	t⊓	_	0.5	50	ms	
Power shutoff time	t off	_	1	_	ms	For repeated operation

Note: Be sure that the power supply will come on within the selected oscillator stabilization period. Also, when varying the supply voltage during operation, it is recommended that the supply voltage be increased gradually.

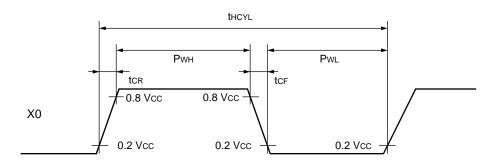


(3) Clock Timing Standards

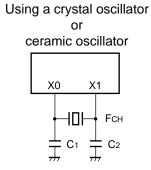
(AVss = Vss = 0 V,
$$T_A = -40$$
 °C to +85 °C)

Parameter	Symbol	Pin name	Condi-		Value		Unit	Remarks	
Farameter	Syllibol	Fili lialile	tion	Min	Тур	Max	Oille	Kemarks	
Clock frequency	Fсн	X0, X1		1	_	12.5	MHz	Main clock	
Clock frequency	FcL	X0A, X1A			32.768		kHz	Sub clock	
Clock cycle time	t HCYL	X0, X1		80	_	1000	ns	Main clock	
Clock cycle time	t LCYL	X0A, X1A		_	30.5	_	μs	Sub clock	
Input clock pulse width	Pwh Pwl	X0		20	_	_	ns	External clock	
Input clock pulse width	Pwhh Pwll	X0A		_	15.2	_	μs	External clock	
Input clock rise, fall time	tcr tcr	X0			_	10	ns	External clock	

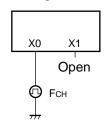
• X0, X1 timing and application conditions



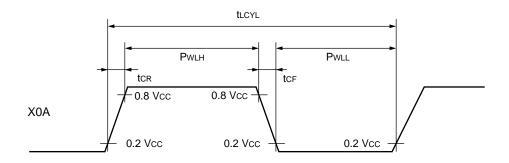
• Clock application conditions



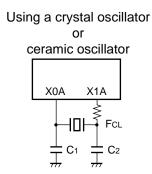
Using an external clock signal



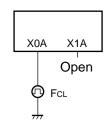
• X0A, X1A timing and application conditions



• Clock application conditions



Using an external clock signal



(4) Instruction Cycle

(AVss = Vss = 0 V, $T_A = -40$ °C to +85 °C)

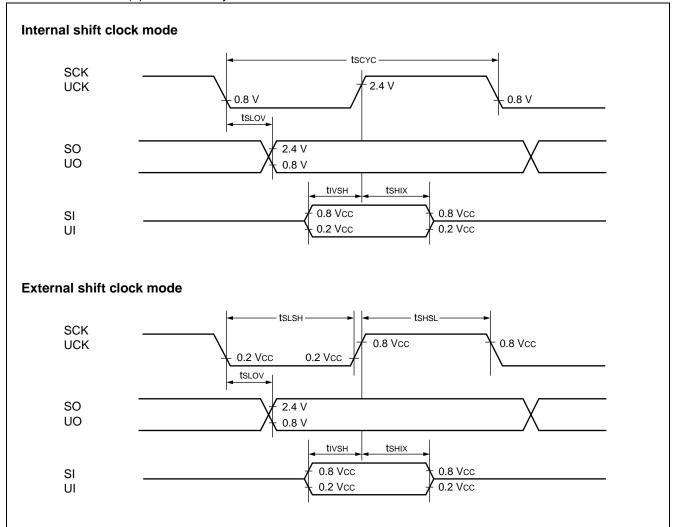
Parameter	Symbol	Rated value	Unit	Remarks
Instruction cycle (minimum instruction execution time)	t inst	4/Гсн, 8/Гсн, 16/Гсн, 64/Гсн	μs	Operating at F _{CH} = 12.5 MHz (4/F _{CH}) t _{inst} = 0.32 μs
		2/FcL	μs	Operating at F _{CL} = 32.768 kHz t_{inst} = 61.036 μs

(5) Serial I/O Timing

(Vcc = 5.0 V, AVss = Vss = 0 V, $T_A = -40 \, ^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$)

Parameter	Sym-	Pin name	Condition	Va	lue	Unit	Remarks
Parameter	bol	Pili liaille	Condition	Min	Max		Remarks
Serial clock cycle time	t scyc	SCK, UCK		2 tinst	_	μs	
SCK↓→SO	t slov	SCK, SO, UCK, UO	Internal	-200	+200	ns	
Valid SI→SCK↑	t ıvsh	SI, SCK, UI, UCK	clock operation	200		ns	
SCK↑→valid SI hold time	t shix	SCK, SI, UCK, UI		200	_	ns	
Serial clock "H" pulse width	t shsl	SCK, UCK		1 tinst	_	μs	
Serial clock "L" pulse width	t slsh	SCK, UCK	External	1 tinst	_	μs	
SCK↓→SO time	t slov	SCK, SO, UCK, UO	clock	0	200	ns	
Valid SI→SCK↑	t ıvsh	SI, SCK, UI, UCK	operation	200	_	ns	
SCK [↑] → valid SI hold time	t shix	SCK, SI, UCK, UI		200	_	ns	

Note: For tinst see " (4) Instruction Cycle".

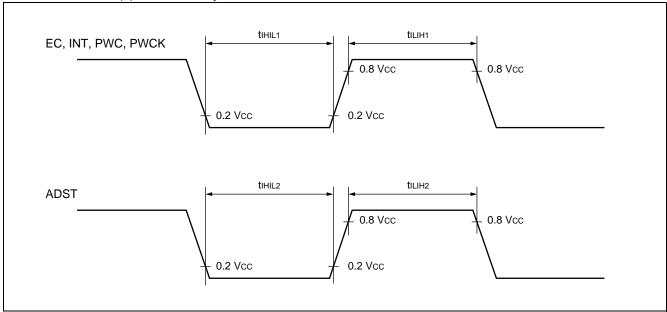


(6) Peripheral Input Timing

(Vcc = 5.0 V, AVss = Vss = 0 V, $T_A = -40 \, ^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$)

Parameter	Symbol	Pin name	Condition	Val	lue	Unit	Remarks
Faranietei	Syllibol	Fili lialile	Condition	Min	Max	Oill	Neillaiks
Peripheral input "H" level pulse width 1	t ıLıH1	INT10 to INT13, INT20 to INT27,		2 tinst	_	μs	
Peripheral input "L" level pulse width 1	tıHIL1	EC, PWC, PWCK	_	2 tinst	_	μs	
Peripheral input "H" level pulse width 2	t ıLıH2	ADST		2 ⁸ t _{inst}	_	μs	
Peripheral input "L" level pulse width 2	t _{IHIL2}	ADST	_	2 ⁸ t _{inst}	_	μs	

Note: For tinst see "(4) Instruction Cycle".



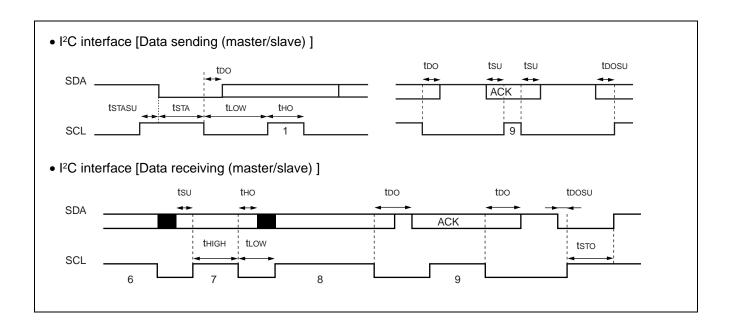
(7) I²C Timing

 $(Vcc = 5.0 \text{ V}, \text{ AVss} = \text{Vss} = 0 \text{ V}, \text{ T}_A = -40 \, ^{\circ}\text{C} \text{ to } +85 \, ^{\circ}\text{C})$

Parameter	Symbol	Pin	Condition	Val	ue	Unit	Remarks
Parameter	Symbol	name	Condition	Min	Max	Offic	Remarks
Start condition output	t sta	SCL SDA	_	$\begin{array}{c} 1 \; / \; 4 \; t_{inst} \times \\ m \times n - 20 \end{array}$	$\begin{array}{l} 1 \; / \; 4 \; t_{inst} \times \\ m \times n + 20 \end{array}$	ns	Master only
Stop condition output	t sто	SCL SDA	_	$\begin{array}{c} 1 \ / \ 4 \ t_{inst} \times \\ (m \times n + 8) \ - 20 \end{array}$	$\begin{array}{c} 1 \ / \ 4 \ t_{inst} \times \\ (m \times n + 8) \ + 20 \end{array}$	ns	Master only
Start condition detection	t sta	SCL SDA	_	$1 \ / \ 4 \ t_{\text{inst}} \times 6 + 40$		ns	
Stop condition detection	t sто	SCL SDA	_	$1 \ / \ 4 \ t_{inst} \times 6 + 40$		ns	
Restart condition output	t stasu	SCL SDA	_	$\begin{array}{c} 1 \ / \ 4 \ t_{inst} \times \\ (m \times n + 8) \ - 20 \end{array}$	$\begin{array}{c} 1 \ / \ 4 \ t_{inst} \times \\ (m \times n + 8) \ + 20 \end{array}$	ns	Master only
Restart condition detection	t stasu	SCL SDA	_	1 / 4 t _{inst} × 4 + 40	_	ns	
SCL output "L" width	t LOW	SCL	_	$\begin{array}{l} 1 \; / \; 4 \; t_{inst} \times \\ m \times n - 20 \end{array}$	$\begin{array}{l} 1 \; / \; 4 \; t_{inst} \times \\ m \times n \; + \; 20 \end{array}$	ns	Master only
SCL output "H" width	t HIGH	SCL	_	$\begin{array}{c} 1 \ / \ 4 \ t_{inst} \times \\ (m \times n + 8) \ - 20 \end{array}$	$\begin{array}{c} 1 \ / \ 4 \ t_{inst} \times \\ (m \times n + 8) \ + 20 \end{array}$	ns	Master only
SDA output delay time	t₀o	SDA		$1~/~4~t_{\text{inst}}\times 4-20$	$1~/~4~t_{\text{inst}}\times 4+20$	ns	
Setup after SDA output interrupt interval	t DOSU	SDA	_	1 / 4 t _{inst} × 4 – 20	_	ns	
SCL input "L" width	t LOW	SCL		$1 / 4 t_{inst} \times 6 + 40$	_	ns	
SCL input "H" width	t HIGH	SCL	_	$1 / 4 t_{inst} \times 2 + 40$	_	ns	
SDA input setup	t su	SDA	_	40	_	ns	
SDA input hold	tно	SDA		0		ns	

Notes: • For t_{inst} see " (4) Instruction Cycle".

- The value "m" in the above table is the value from the shift clock frequency setting bits (CS4-CS3) in the clock control register "ICCR". For details, refer to the register description in the hardware manual.
- The value 'n' in the above table is the value from the shift clock frequency setting bits (CS2-CS0) in the clock control register "ICCR". For details, refer to the register description in the hardware manual.
- toosu appears when the interrupt period is longer than the SCL "L" width.
- The rated values for SDA and SCL assume a start up time of 0 ns.



5. A/D Converter Electrical Characteristics

(1) MB89535A/537A/537AC/538A/538AC/P538/PV538

(Vcc = 3.5 V to 5.5 V, AVss = Vss = 0 V, $T_A = -40$ °C to +85 °C)

Parameter	Symbol	Pin name	Condition		Value		Unit	Remarks
Farameter	Symbol	r III IIaiiie	Condition	Min	Тур	Max	Offic	iveillai və
Resolution capability			_			10	bit	
Total error					_	±3.0	LSB	
Linear error					_	±2.5	LSB	
Differential linear error					_	±1.9	LSB	
Zero transition voltage	Vот	_	AVR = AVcc	AVss-1.5 LSB	AVss+0.5 LSB	AVss+2.5 LSB	mV	AVcc = Vcc
Full scale transition voltage	V _{FST}			AVR – 3.5 LSB	AVR – 1.5 LSB	AVR+1.5 LSB	mV	
Inter-channel variation						4.0	LSB	
Conversion time	<u> </u>			_	60 tinst	_	μs	*
Sampling time					16 tinst	_	μs	
Analog input current	Iain	AN0 to			_	10	μΑ	
Analog input voltage	Vain	AN7		0	_	AVR	V	
Reference voltage	_			AVss + 3.5	_	AVcc	V	
Reference voltage	IR	AVR	A/D running	_	400	_	μΑ	
supply current	lкн		A/D off	_		5	μΑ	

^{*:} Includes sampling time.

Note: For tinst see " (4) Instruction Cycle".

(2) MB89F538

(Vcc = 3.5 V to 5.5 V, AVss = Vss = 0 V, $T_A = -40$ °C to +85 °C)

Parameter	Symbol	Pin name	Condition		Value		Unit	Remarks
Farameter	Syllibol	r III IIaiiie	Condition	Min	Тур	Max	Offic	iveillai va
Resolution capability			_	_	_	10	bit	
Total error						±5.0	LSB	
Linear error				_	_	±2.5	LSB	
Differential linear error				_	_	±1.9	LSB	
Zero transition voltage	Vот	_	AVR = AVcc	AVss-1.5 LSB	AVss+0.5 LSB	AVss+4.5 LSB	mV	AVcc = Vcc
Full scale transition voltage	V _{FST}			AVR – 6.5 LSB	AVR – 1.5 LSB	AVR+1.5 LSB	mV	
Inter-channel variation					_	4.0	LSB	
Conversion time				_	60 tinst	_	μs	*
Sampling time					16 tinst	_	μs	
Analog input current	Iain	AN0 to				10	μΑ	
Analog input voltage	Vain	AN7		0		AVR	V	
Reference voltage				AVss + 3.5		AVcc	V	
Reference voltage	IR	AVR	A/D running		400	_	μΑ	
supply current	I _{RH}		A/D off			5	μΑ	

^{*:} Includes sampling time.

Note: For tinst see " (4) Instruction Cycle".

(3) A/D Converter Terms and Definitions

Resolution

The level of analog variation that can be distinguished by the A/D converter.

• Linear error (unit : LSB)

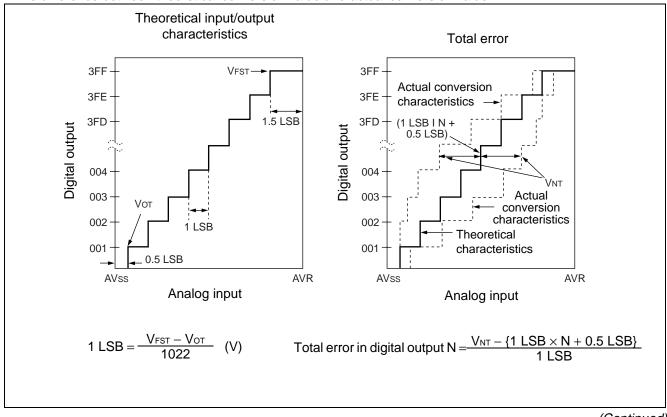
The deviation between the value along a straight line connecting the zero transition point ("00 0000 0000" $\leftarrow \rightarrow$ "00 0000 0001") of a device and the full-scale transition point ("11 1111 1110" $\leftarrow \rightarrow$ "11 1111 1111"), compared with the actual conversion values obtained.

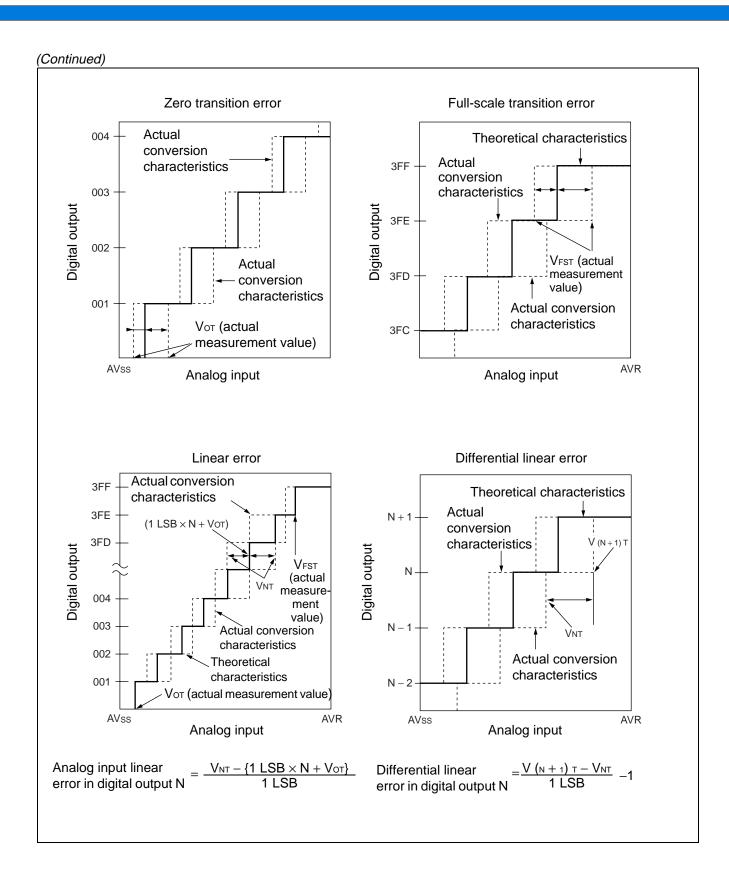
• Differential linear error (Unit: LSB)

The deviation from the theoretical input voltage required to produce a change of 1 LSB in output code.

• Total error (Unit : LSB)

The difference between theoretical conversion value and actual conversion value.

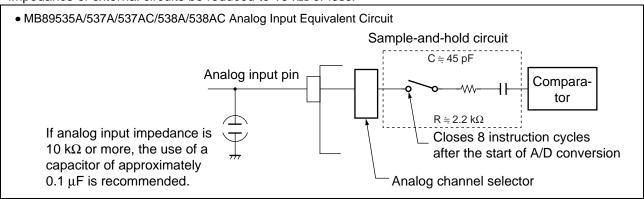


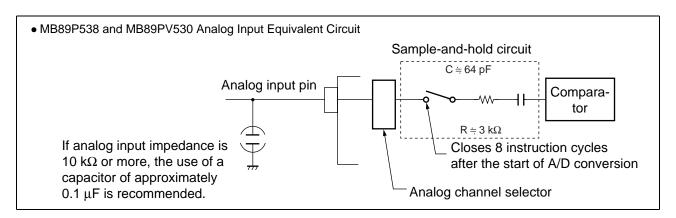


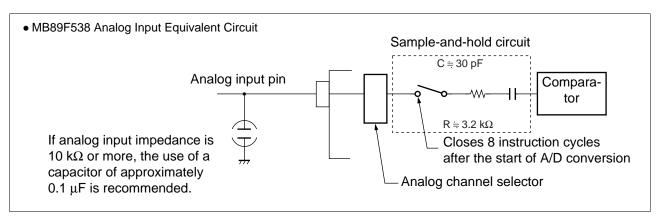
(4) Precautionary Information

• Input Impedance of Analog Input Pins

The A/D converter of MB89530A has a sample & hold circuit as shown below, which uses a sample-and-hold capacitor to obtain the voltage at the analog input pin for 8 instruction cycles following the start of A/D conversion. For this reason if the external circuits providing the analog input signal have high output impedance, the analog input voltage may not stabilize within the analog input sampling time. It is therefore recommended that the output impedance of external circuits be reduced to 10 k Ω or less.





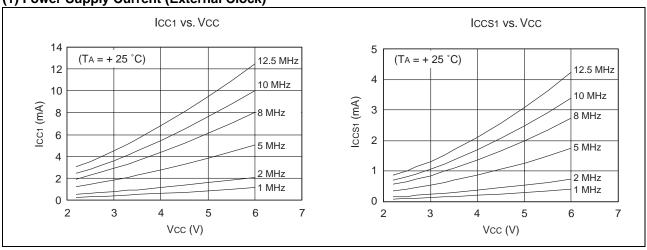


About error

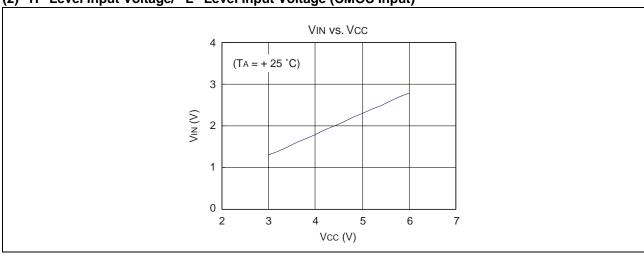
The smaller the absolute value |AVR - AVss| is, the greater the relative error becomes.

■ EXAMPLE CHARACTERISTICS (MB89538A)

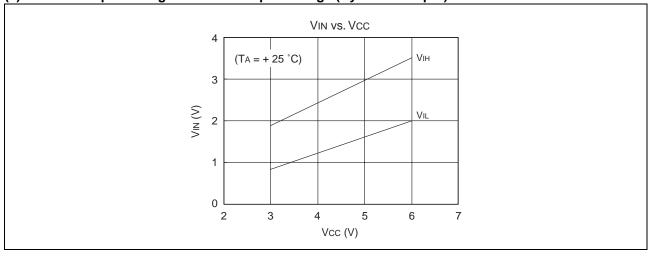
(1) Power Supply Current (External Clock)



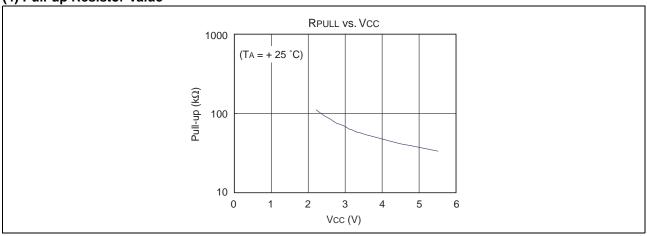
(2) "H" Level Input Voltage/ "L" Level Input Voltage (CMOS Input)



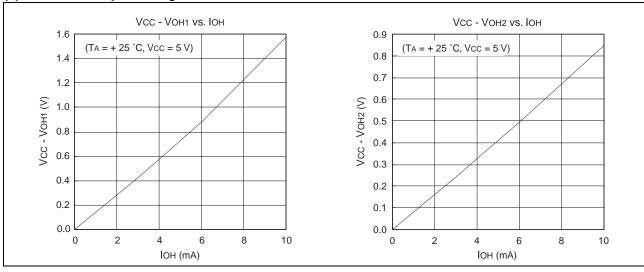
(3) "H" Level Input Voltage / "L" Level Input Voltage (Hysteresis Input)



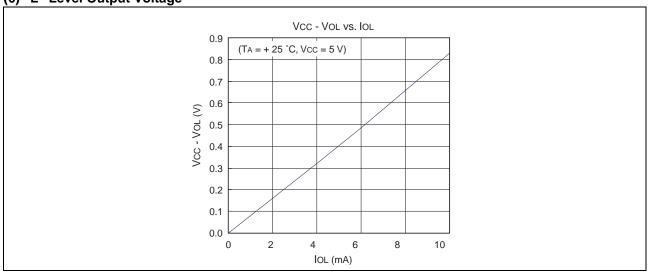
(4) Pull-up Resistor Value

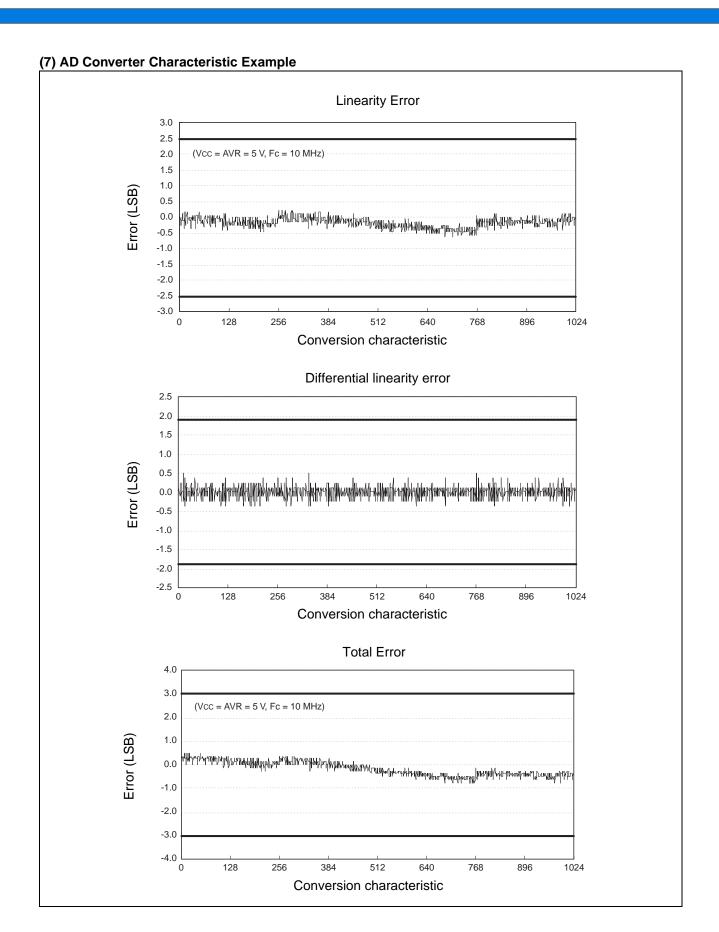


(5) "H" Level Output Voltage









■ MASK OPTIONS

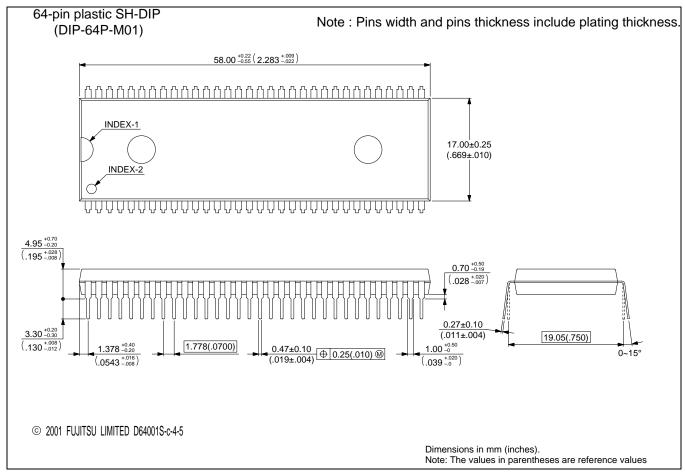
No	Part number	MB89535A MB89537A MB89537AC MB89538A MB89538AC	MB89F538-101 MB89F538-201	MB89P538-101 MB89P538-201	MB89PV530-101 MB89PV530-201
	Method of specification	Specify at time of mask order	Setting not possible	Setting not possible	Setting not possible
1	Main clock Select oscillator stabilization wait period (FcH* = 10 MHz) approx.2 ¹⁴ /FcH* (approx.1.6 ms) approx.2 ¹⁷ /FcH* (approx.13.1 ms) approx.2 ¹⁸ /FcH* (approx.26.2 ms)	Selection available	2 ¹⁸ /F _{сн} * (approx. 26.2 ms)	2 ¹⁸ /F _{CH} * (approx. 26.2 ms)	2 ¹⁸ /F _{сн} * (арргох. 26.2 ms)
2	Clock mode selection • 2-system clock mode • 1-system clock mode	Selection available		1 : 1-system clock mo 1 : 2-system clock mo	

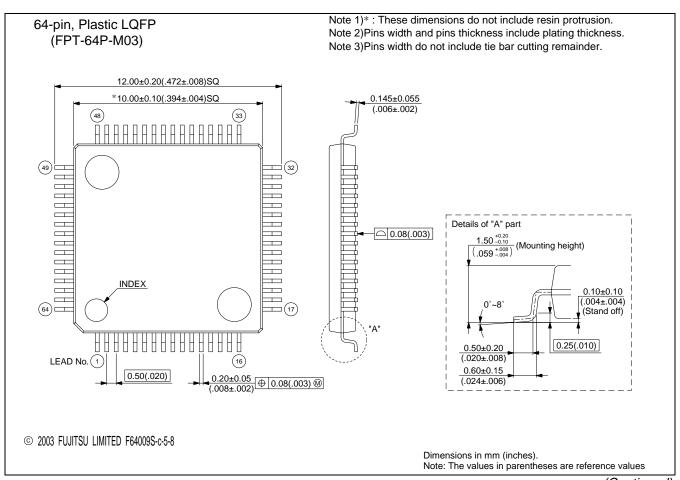
^{* :} Fcн: Main clock frequency

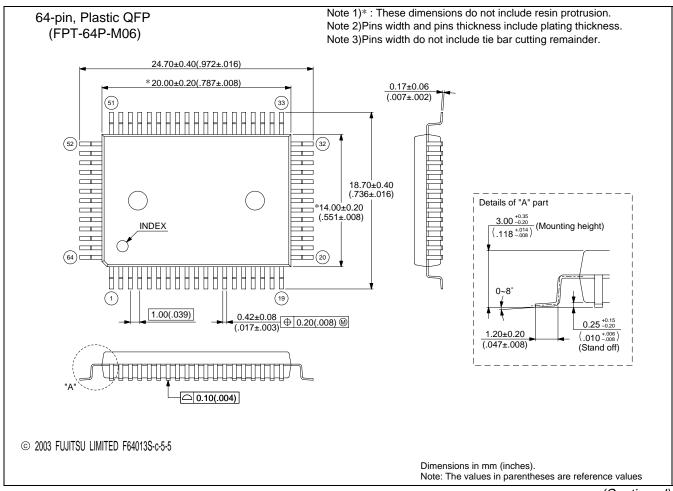
■ ORDERING INFORMATION

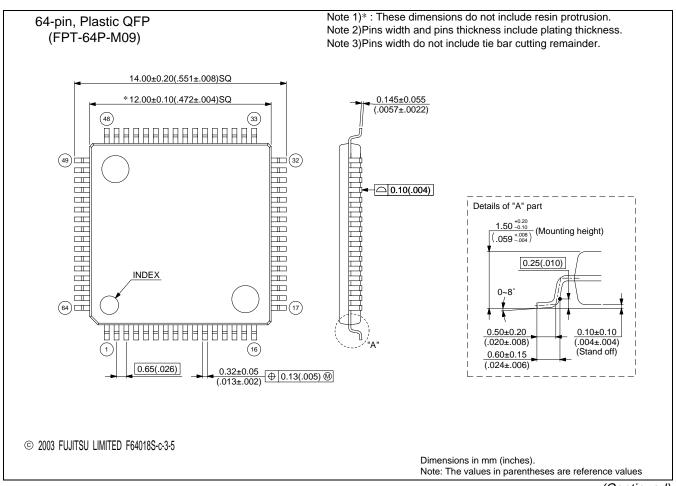
Part number	Package	Remarks
MB89535AP MB89537AP MB89537ACP MB89538AP MB89538ACP MB89P538P-101 MB89P538P-201 MB89F538P-201 MB89F538P-201	DIP-64P-M01	MB89535AP, MB89537AP and MB89538AP do not have I ² C functions.
MB89535APF MB89537APF MB89537ACPF MB89538APF MB89538ACPF MB89P538PF-101 MB89P538PF-201 MB89F538PF-101 MB89F538PF-201	FPT-64P-M06	MB89535APF, MB89537APF and MB89538APF do not have I ² C functions.
MB89535APFM MB89537APFM MB89537ACPFM MB89538APFM MB89538ACPFM MB89P538PFM-101 MB89P538PFM-201 MB89F538PFM-101 MB89F538PFM-201	FPT-64P-M09	MB89535APFM, MB89537APFM and MB89538APFM do not have I ² C functions.
MB89535APFV MB89537APFV MB89537ACPFV MB89538APFV MB89538ACPFV	FPT-64P-M03	MB89535APFV, MB89537APFV and MB89538APFV do not have I ² C functions.
MB89PV530C-101 MB89PV530C-201	MDP-64C-P02	
MB89PV530CF-101 MB89PV530CF-201	MQP-64C-P01	

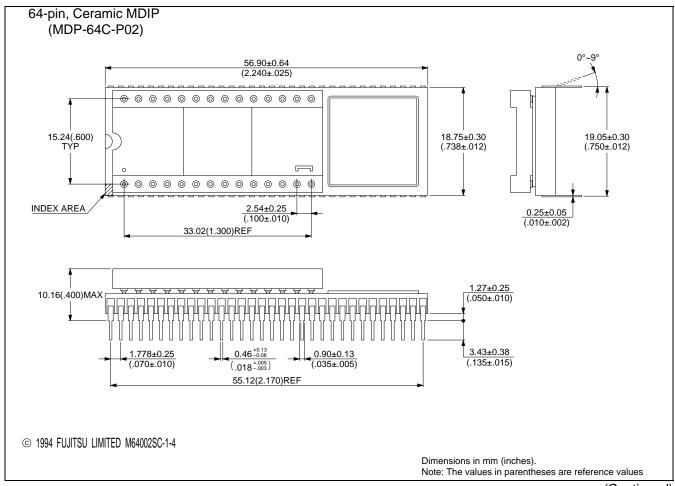
■ PACKAGE DIMENSIONS

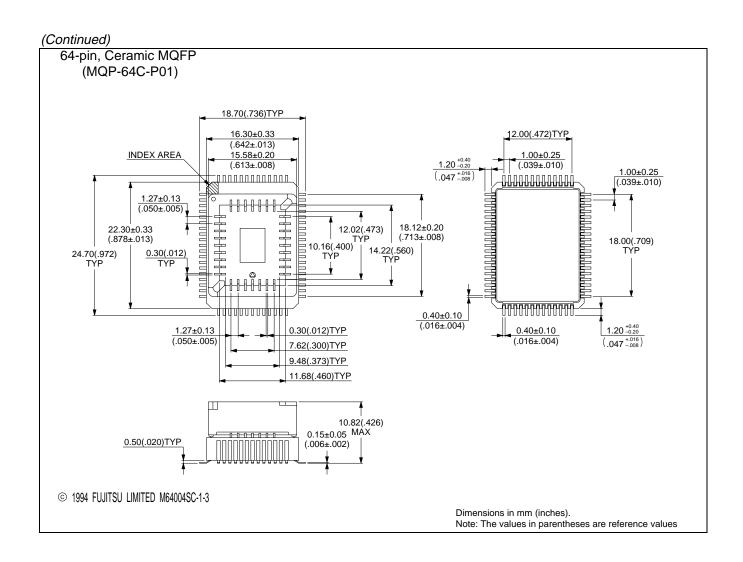












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